S-817 Series

SUPER-SMALL PACKAGE CMOS VOLTAGE REGULATOR

www.sii-ic.com

Rev.6.1_00

The S-817 Series is a 3-terminal positive voltage regulator, developed using CMOS technology. Small ceramic capacitors can be used as the output capacitor, and the S-817 series provides stable operation with low loads down to 1 μA.
Compared with the conventional voltage regulator, it is of low current consumption, and with a lineup of the super small package (SNT-4A:1.2 x 1.6mm). It is optimal as a power supply of small portable device.

■ Features

- Ultra-low current consumption: Operating current: Typ. 1.2 μA, Max. 2.5 μA
- Output voltage: 1.1 to 6.0 V, selectable in 0.1 V steps.
- Output voltage accuracy: ±2.0%
- Output current: 50 mA capable (3.0 V output product, V_{IN}=5 V) *1
  75 mA capable (5.0 V output product, V_{IN}=7 V) *1
- Dropout voltage: Typ. 160 mV (V_{OUT} = 5.0 V, I_{OUT} = 10 mA)
- Low ESR capacitor Ceramic capacitor of 0.1 μF or more can be used as an output capacitor.
- Short circuit protection for: Series A
- Excellent Line Regulation: Stable operation at light load of 1 μA
- Lead-free, Sn 100%, halogen-free*2

***1.** Attention should be paid to the power dissipation of the package when the load is large.
***2.** Refer to "■ **Product Name Structure**" for details.

■ Applications

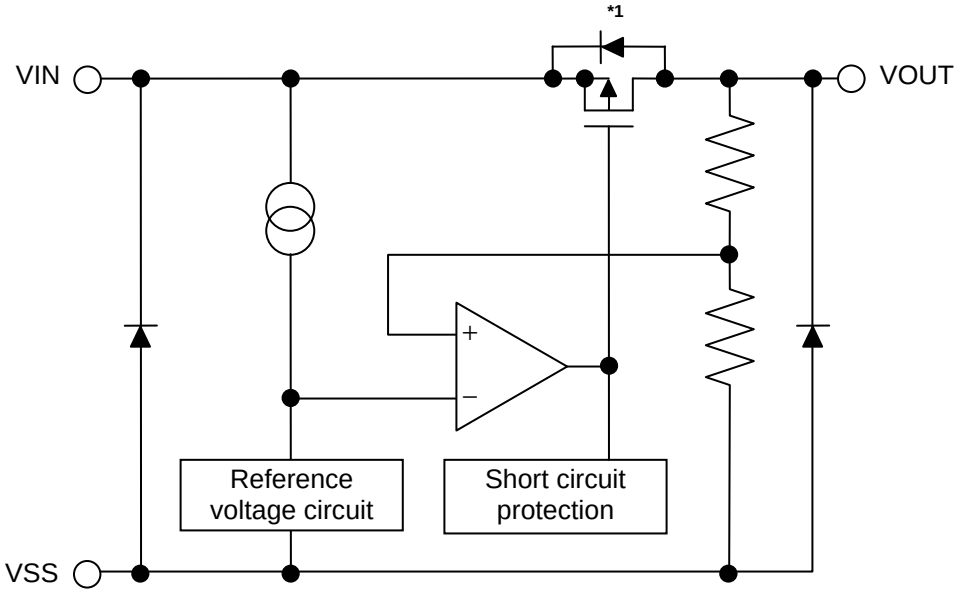
- Power source for battery-powered devices
- Power source for personal communication devices
- Power source for home electric/electronic appliances

■ Packages

- SNT-4A
- SC-82AB
- SOT-23-5
- SOT-89-3
- TO-92

■ Block Diagrams

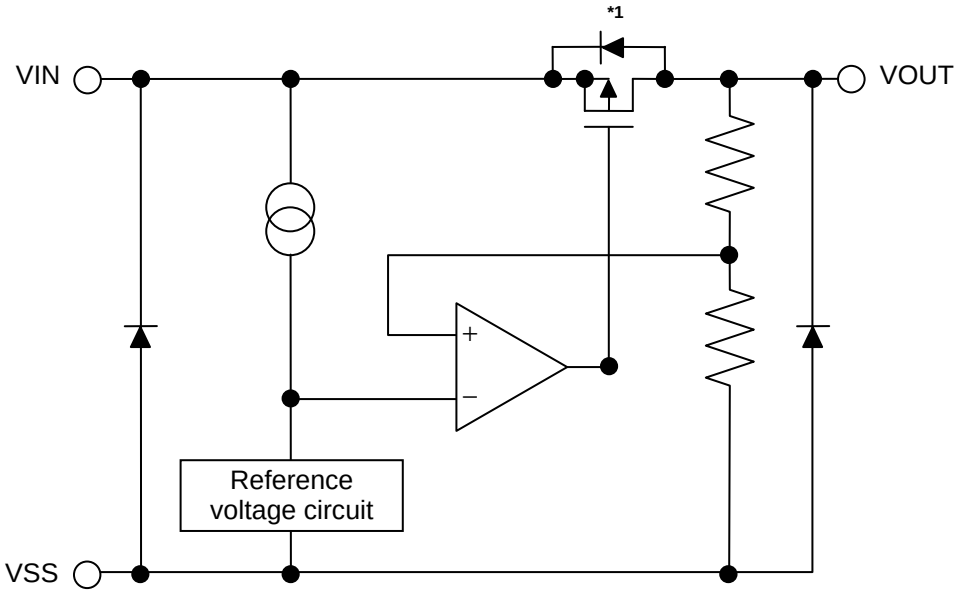
1. S-817A Series



***1.** Parasitic diode

Figure 1

2. S-817B Series



***1.** Parasitic diode

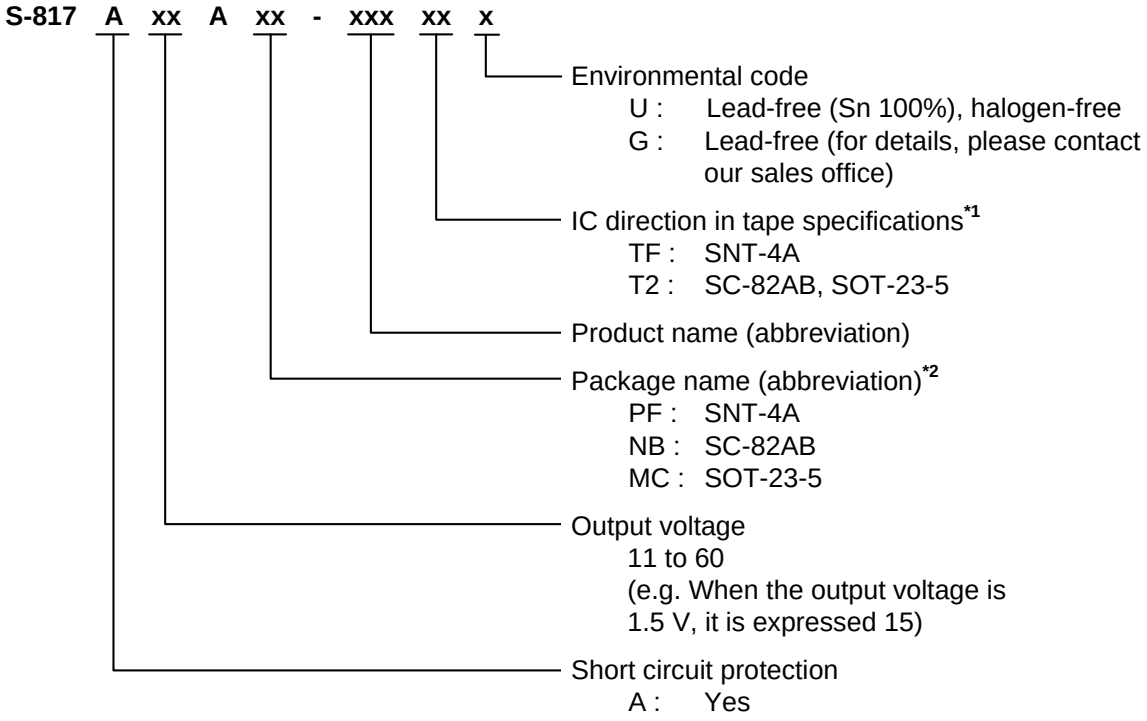
Figure 2

■ Product Name Structure

- The product types and output voltage for the S-817 Series can be selected at the user's request. Refer to the "**1. Product Name**" for the construction of the product name, "**2. Package**" regarding the package drawings and "**3. Product Name List**" for the full product names.

1. Product name

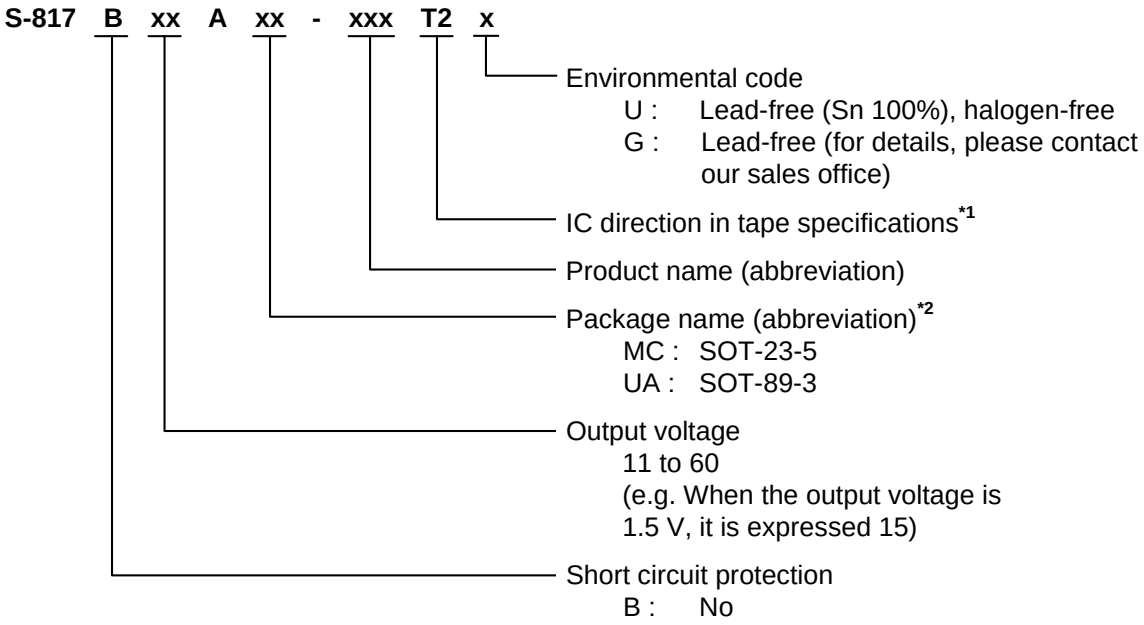
1. 1 S-817A series



***1.** Refer to the tape specifications at the end of this book.
***2.** Refer to the "**3. Product name list**".

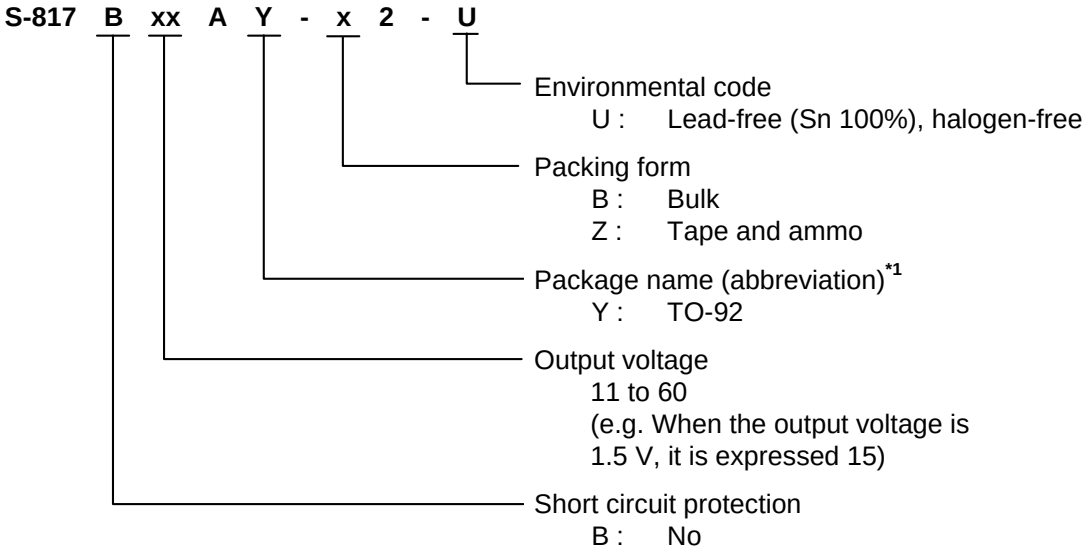
1. 2 S-817B series

1. 2. 1 SOT-23-5 and SOT-89-3 package



***1.** Refer to the tape specifications at the end of this book.
***2.** Refer to the "**3. Product name list**".

1. 2. 2 TO-92 package



***1.** Refer to the "**3. Product name list**".

2. Package

Package name	Drawing code				
	Package	Tape	Reel	Zigzag	Land
SNT-4A	PF004-A-P-SD	PF004-A-C-SD	PF004-A-R-SD	—	PF004-A-L-SD
SC-82AB	NP004-A-P-SD	NP004-A-C-SD NP004-A-C-S1	NP004-A-R-SD	—	—
SOT-23-5	MP005-A-P-SD	MP005-A-C-SD	MP005-A-R-SD	—	—
SOT-89-3	UP003-A-P-SD	UP003-A-C-SD	UP003-A-R-SD	—	—
TO-92 (Bulk)	YS003-D-P-SD	—	—	—	—
TO-92 (Tape and ammo)	YZ003-E-P-SD	YZ003-E-C-SD	—	YZ003-E-Z-SD	—

3. Product name list

3. 1 S-817A series

Table 1

Output voltage	SNT-4A	SC-82AB	SOT-23-5
1.1 V ± 2.0 %	S-817A11APF-CUATFx	S-817A11ANB-CUAT2x	—
1.2 V ± 2.0 %	S-817A12APF-CUBTFx	S-817A12ANB-CUBT2x	—
1.3 V ± 2.0 %	S-817A13APF-CUCTFx	S-817A13ANB-CUCT2x	—
1.4 V ± 2.0 %	S-817A14APF-CUDTFx	S-817A14ANB-CUDT2x	S-817A14AMC-CUDT2x
1.5 V ± 2.0 %	S-817A15APF-CUETFx	S-817A15ANB-CUET2x	—
1.6 V ± 2.0 %	S-817A16APF-CUFTFx	S-817A16ANB-CUFT2x	S-817A16AMC-CUFT2x
1.7 V ± 2.0 %	S-817A17APF-CUGTFx	S-817A17ANB-CUGT2x	—
1.8 V ± 2.0 %	S-817A18APF-CUHTFx	S-817A18ANB-CUHT2x	—
1.9 V ± 2.0 %	S-817A19APF-CUITFx	S-817A19ANB-CUIT2x	—
2.0 V ± 2.0 %	S-817A20APF-CUJTFx	S-817A20ANB-CUJT2x	—
2.1 V ± 2.0 %	S-817A21APF-CUKTFx	S-817A21ANB-CUKT2x	—
2.2 V ± 2.0 %	S-817A22APF-CULTFx	S-817A22ANB-CULT2x	—
2.3 V ± 2.0 %	S-817A23APF-CUMTFx	S-817A23ANB-CUMT2x	—
2.4 V ± 2.0 %	S-817A24APF-CUNTFx	S-817A24ANB-CUNT2x	—
2.5 V ± 2.0 %	S-817A25APF-CUOTFx	S-817A25ANB-CUOT2x	—
2.6 V ± 2.0 %	S-817A26APF-CUPTFx	S-817A26ANB-CUPT2x	—
2.7 V ± 2.0 %	S-817A27APF-CUQTFx	S-817A27ANB-CUQT2x	—
2.8 V ± 2.0 %	S-817A28APF-CURTFx	S-817A28ANB-CURT2x	—
2.9 V ± 2.0 %	S-817A29APF-CUSTFx	S-817A29ANB-CUST2x	—
3.0 V ± 2.0 %	S-817A30APF-CUTTFx	S-817A30ANB-CUTT2x	—
3.1 V ± 2.0 %	S-817A31APF-CUUTFx	S-817A31ANB-CUUT2x	—
3.2 V ± 2.0 %	S-817A32APF-CUVTFx	S-817A32ANB-CUVT2x	—
3.3 V ± 2.0 %	S-817A33APF-CUWTFx	S-817A33ANB-CUWT2x	—
3.4 V ± 2.0 %	S-817A34APF-CUXTFx	S-817A34ANB-CUXT2x	—
3.5 V ± 2.0 %	S-817A35APF-CUYTFx	S-817A35ANB-CUYT2x	—
3.6 V ± 2.0 %	S-817A36APF-CUZTFx	S-817A36ANB-CUZT2x	—
3.7 V ± 2.0 %	S-817A37APF-CVATFx	S-817A37ANB-CVAT2x	—
3.8 V ± 2.0 %	S-817A38APF-CVBTFx	S-817A38ANB-CVBT2x	—
3.9 V ± 2.0 %	S-817A39APF-CVCTFx	S-817A39ANB-CVCT2x	—
4.0 V ± 2.0 %	S-817A40APF-CVDTFx	S-817A40ANB-CVDT2x	—
4.1 V ± 2.0 %	S-817A41APF-CVETFx	S-817A41ANB-CVET2x	—
4.2 V ± 2.0 %	S-817A42APF-CVFTFx	S-817A42ANB-CVFT2x	—
4.3 V ± 2.0 %	S-817A43APF-CVGTFx	S-817A43ANB-CVGT2x	—
4.4 V ± 2.0 %	S-817A44APF-CVHTFx	S-817A44ANB-CVHT2x	—
4.5 V ± 2.0 %	S-817A45APF-CVITFx	S-817A45ANB-CVIT2x	—
4.6 V ± 2.0 %	S-817A46APF-CVJTFx	S-817A46ANB-CVJT2x	—
4.7 V ± 2.0 %	S-817A47APF-CVKTFx	S-817A47ANB-CVKT2x	—
4.8 V ± 2.0 %	S-817A48APF-CVLTFx	S-817A48ANB-CVLT2x	—
4.9 V ± 2.0 %	S-817A49APF-CVMTFx	S-817A49ANB-CVMT2x	—
5.0 V ± 2.0 %	S-817A50APF-CVNTFx	S-817A50ANB-CVNT2x	—
5.1 V ± 2.0 %	S-817A51APF-CVOTFx	S-817A51ANB-CVOT2x	—
5.2 V ± 2.0 %	S-817A52APF-CVPTFx	S-817A52ANB-CVPT2x	—
5.3 V ± 2.0 %	S-817A53APF-CVQTFx	S-817A53ANB-CVQT2x	—
5.4 V ± 2.0 %	S-817A54APF-CVRTFx	S-817A54ANB-CVRT2x	—
5.5 V ± 2.0 %	S-817A55APF-CVSTFx	S-817A55ANB-CVST2x	—
5.6 V ± 2.0 %	S-817A56APF-CVTTFx	S-817A56ANB-CVTT2x	—
5.7 V ± 2.0 %	S-817A57APF-CVUTFx	S-817A57ANB-CVUT2x	—
5.8 V ± 2.0 %	S-817A58APF-CVVTFx	S-817A58ANB-CVVT2x	—
5.9 V ± 2.0 %	S-817A59APF-CVWTFx	S-817A59ANB-CVWT2x	—
6.0 V ± 2.0 %	S-817A60APF-CVXTFx	S-817A60ANB-CVXT2x	—

Remark 1. Please contact the SII marketing department for products with an output voltage over than those specified above.
2. x: G or U
3. Please select products of environmental code = U for Sn 100%, halogen-free products.

3. 2 S-817B series

Table 2

Output voltage	SOT-23-5	SOT-89-3	TO-92*1
1.1 V ± 2.0 %	S-817B11AMC-CWAT2x	S-817B11AUA-CWAT2x	S-817B11AY-n2-U
1.2 V ± 2.0 %	S-817B12AMC-CWBT2x	S-817B12AUA-CWBT2x	S-817B12AY-n2-U
1.3 V ± 2.0 %	S-817B13AMC-CWCT2x	S-817B13AUA-CWCT2x	S-817B13AY-n2-U
1.4 V ± 2.0 %	S-817B14AMC-CWDT2x	S-817B14AUA-CWDT2x	S-817B14AY-n2-U
1.5 V ± 2.0 %	S-817B15AMC-CWET2x	S-817B15AUA-CWET2x	S-817B15AY-n2-U
1.6 V ± 2.0 %	S-817B16AMC-CWFT2x	S-817B16AUA-CWFT2x	S-817B16AY-n2-U
1.7 V ± 2.0 %	S-817B17AMC-CWGT2x	S-817B17AUA-CWGT2x	S-817B17AY-n2-U
1.8 V ± 2.0 %	S-817B18AMC-CWHT2x	S-817B18AUA-CWHT2x	S-817B18AY-n2-U
1.9 V ± 2.0 %	S-817B19AMC-CWIT2x	S-817B19AUA-CWIT2x	S-817B19AY-n2-U
2.0 V ± 2.0 %	S-817B20AMC-CWJT2x	S-817B20AUA-CWJT2x	S-817B20AY-n2-U
2.1 V ± 2.0 %	S-817B21AMC-CWKT2x	S-817B21AUA-CWKT2x	S-817B21AY-n2-U
2.2 V ± 2.0 %	S-817B22AMC-CWLT2x	S-817B22AUA-CWLT2x	S-817B22AY-n2-U
2.3 V ± 2.0 %	S-817B23AMC-CWMT2x	S-817B23AUA-CWMT2x	S-817B23AY-n2-U
2.4 V ± 2.0 %	S-817B24AMC-CWNT2x	S-817B24AUA-CWNT2x	S-817B24AY-n2-U
2.5 V ± 2.0 %	S-817B25AMC-CWOT2x	S-817B25AUA-CWOT2x	S-817B25AY-n2-U
2.6 V ± 2.0 %	S-817B26AMC-CWPT2x	S-817B26AUA-CWPT2x	S-817B26AY-n2-U
2.7 V ± 2.0 %	S-817B27AMC-CWQT2x	S-817B27AUA-CWQT2x	S-817B27AY-n2-U
2.8 V ± 2.0 %	S-817B28AMC-CWRT2x	S-817B28AUA-CWRT2x	S-817B28AY-n2-U
2.9 V ± 2.0 %	S-817B29AMC-CWST2x	S-817B29AUA-CWST2x	S-817B29AY-n2-U
3.0 V ± 2.0 %	S-817B30AMC-CWTT2x	S-817B30AUA-CWTT2x	S-817B30AY-n2-U
3.1 V ± 2.0 %	S-817B31AMC-CWUT2x	S-817B31AUA-CWUT2x	S-817B31AY-n2-U
3.2 V ± 2.0 %	S-817B32AMC-CWVT2x	S-817B32AUA-CWVT2x	S-817B32AY-n2-U
3.3 V ± 2.0 %	S-817B33AMC-CWWT2x	S-817B33AUA-CWWT2x	S-817B33AY-n2-U
3.4 V ± 2.0 %	S-817B34AMC-CWXT2x	S-817B34AUA-CWXT2x	S-817B34AY-n2-U
3.5 V ± 2.0 %	S-817B35AMC-CWYT2x	S-817B35AUA-CWYT2x	S-817B35AY-n2-U
3.6 V ± 2.0 %	S-817B36AMC-CWZT2x	S-817B36AUA-CWZT2x	S-817B36AY-n2-U
3.7 V ± 2.0 %	S-817B37AMC-CXAT2x	S-817B37AUA-CXAT2x	S-817B37AY-n2-U
3.8 V ± 2.0 %	S-817B38AMC-CXBT2x	S-817B38AUA-CXBT2x	S-817B38AY-n2-U
3.9 V ± 2.0 %	S-817B39AMC-CXCT2x	S-817B39AUA-CXCT2x	S-817B39AY-n2-U
4.0 V ± 2.0 %	S-817B40AMC-CXDT2x	S-817B40AUA-CXDT2x	S-817B40AY-n2-U
4.1 V ± 2.0 %	S-817B41AMC-CXET2x	S-817B41AUA-CXET2x	S-817B41AY-n2-U
4.2 V ± 2.0 %	S-817B42AMC-CXFT2x	S-817B42AUA-CXFT2x	S-817B42AY-n2-U
4.3 V ± 2.0 %	S-817B43AMC-CXGT2x	S-817B43AUA-CXGT2x	S-817B43AY-n2-U
4.4 V ± 2.0 %	S-817B44AMC-CXHT2x	S-817B44AUA-CXHT2x	S-817B44AY-n2-U
4.5 V ± 2.0 %	S-817B45AMC-CXIT2x	S-817B45AUA-CXIT2x	S-817B45AY-n2-U
4.6 V ± 2.0 %	S-817B46AMC-CXJT2x	S-817B46AUA-CXJT2x	S-817B46AY-n2-U
4.7 V ± 2.0 %	S-817B47AMC-CXKT2x	S-817B47AUA-CXKT2x	S-817B47AY-n2-U
4.8 V ± 2.0 %	S-817B48AMC-CXLT2x	S-817B48AUA-CXLT2x	S-817B48AY-n2-U
4.9 V ± 2.0 %	S-817B49AMC-CXMT2x	S-817B49AUA-CXMT2x	S-817B49AY-n2-U
5.0 V ± 2.0 %	S-817B50AMC-CXNT2x	S-817B50AUA-CXNT2x	S-817B50AY-n2-U
5.1 V ± 2.0 %	S-817B51AMC-CXOT2x	S-817B51AUA-CXOT2x	S-817B51AY-n2-U
5.2 V ± 2.0 %	S-817B52AMC-CXPT2x	S-817B52AUA-CXPT2x	S-817B52AY-n2-U
5.3 V ± 2.0 %	S-817B53AMC-CXQT2x	S-817B53AUA-CXQT2x	S-817B53AY-n2-U
5.4 V ± 2.0 %	S-817B54AMC-CXRT2x	S-817B54AUA-CXRT2x	S-817B54AY-n2-U
5.5 V ± 2.0 %	S-817B55AMC-CXST2x	S-817B55AUA-CXST2x	S-817B55AY-n2-U
5.6 V ± 2.0 %	S-817B56AMC-CXTT2x	S-817B56AUA-CXTT2x	S-817B56AY-n2-U
5.7 V ± 2.0 %	S-817B57AMC-CXUT2x	S-817B57AUA-CXUT2x	S-817B57AY-n2-U
5.8 V ± 2.0 %	S-817B58AMC-CXVT2x	S-817B58AUA-CXVT2x	S-817B58AY-n2-U
5.9 V ± 2.0 %	S-817B59AMC-CXWT2x	S-817B59AUA-CXWT2x	S-817B59AY-n2-U
6.0 V ± 2.0 %	S-817B60AMC-CXXT2x	S-817B60AUA-CXXT2x	S-817B60AY-n2-U

***1**. "n" changes according to the packing form in TO-92.
B: Bulk, Z: Tape and ammo.

Remark 1. x: G or U
2. Please select products of environmental code = U for Sn 100%, halogen-free products.

■ Pin Configurations

SNT-4A
Top view

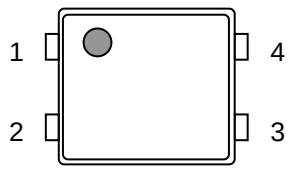


Figure 3

Table 3

Pin No.	Symbol	Description
1	VOUT	Output voltage pin
2	VIN	Input voltage pin
3	VSS	GND pin
4	NC*1	No connection

***1**. The NC pin is electrically open.
The NC pin can be connected to VIN or VSS.

SC-82AB
Top view

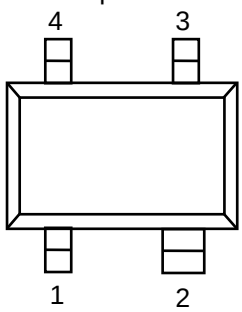


Figure 4

Table 4

Pin No.	Symbol	Description
1	VSS	GND pin
2	VIN	Input voltage pin
3	VOUT	Output voltage pin
4	NC*1	No connection

***1**. The NC pin is electrically open.
The NC pin can be connected to VIN or VSS.

SOT-23-5
Top view

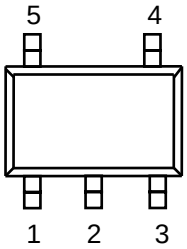


Figure 5

Table 5

Pin No.	Symbol	Description
1	VSS	GND pin
2	VIN	Input voltage pin
3	VOUT	Output voltage pin
4	NC*1	No connection
5	NC*1	No connection

***1**. The NC pin is electrically open.
The NC pin can be connected to VIN or VSS.

SOT-89-3
Top view

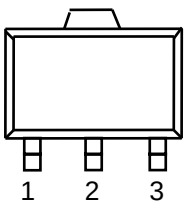


Figure 6

Table 6

Pin No.	Symbol	Description
1	VSS	GND pin
2	VIN	Input voltage pin
3	VOUT	Output voltage pin

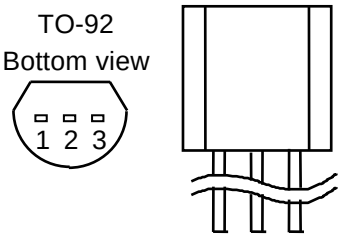


Figure 7

Table 7

Pin No.	Symbol	Description
1	VSS	GND pin
2	VIN	Input voltage pin
3	VOUT	Output voltage pin

■ Absolute Maximum Ratings

Table 8

(Ta=25°C unless otherwise specified)

Item		Symbol	Absolute Maximum Rating	Units
Input voltage		V_{IN}	V_{SS}–0.3 to V_{SS}+12	V
Output voltage		V_{OUT}	V_{SS}–0.3 to V_{IN}+0.3	V
Power dissipation	SNT-4A	P_D	300[*1]	mW
	SC-82AB		150 (When not mounted on board)	mW
			400[*1]	mW
	SOT-23-5		250 (When not mounted on board)	mW
			600[*1]	mW
	SOT-89-3		500 (When not mounted on board)	mW
			1000[*1]	mW
	TO-92		400 (When not mounted on board)	mW
			800[*1]	mW
Operating temperature range		Topr	–40 to +85	°C
Storage temperature		Tstg	–40 to +125	°C

***1.** When mounted on board
[Mounted board]
(1) Board size : 114.3 mm × 76.2 mm × t1.6 mm
(2) Board name : JEDEC STANDARD51-7

Caution The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.

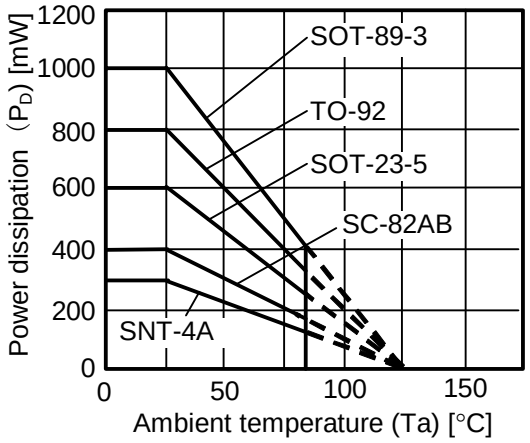


Figure 8 Power dissipation of The package (When mounted on board)

■ Electrical Characteristics

1. S-817A series

Table 9

(Ta=25°C unless otherwise specified)

Item	Symbol	Conditions		Min.	Typ.	Max.	Units	Measurement circuits
Output voltage *1	$V_{OUT(E)}$	$V_{IN}=V_{OUT(S)}+2$ V, $I_{OUT}=10$ mA		$V_{OUT(S)} \times 0.98$	$V_{OUT(S)}$	$V_{OUT(S)} \times 1.02$	V	1
Output current *2	I_{OUT}	$V_{OUT(S)}+2$ V $\le V_{IN} \le 10$ V	1.1 V $\le V_{OUT(S)} \le$ 1.9 V	20	–	–	mA	3
			2.0 V $\le V_{OUT(S)} \le$ 2.9 V	35	–	–		
			3.0 V $\le V_{OUT(S)} \le$ 3.9 V	50	–	–		
			4.0 V $\le V_{OUT(S)} \le$ 4.9 V	65	–	–		
			5.0 V $\le V_{OUT(S)} \le$ 6.0 V	75	–	–		
Dropout voltage *3	V_{drop}	I_{OUT} = 10 mA	1.1 V $\le V_{OUT(S)} \le$ 1.4 V	–	0.92	1.58	V	1
			1.5 V $\le V_{OUT(S)} \le$ 1.9 V	–	0.58	0.99		
			2.0 V $\le V_{OUT(S)} \le$ 2.4 V	–	0.40	0.67		
			2.5 V $\le V_{OUT(S)} \le$ 2.9 V	–	0.31	0.51		
			3.0 V $\le V_{OUT(S)} \le$ 3.4 V	–	0.25	0.41		
			3.5 V $\le V_{OUT(S)} \le$ 3.9 V	–	0.22	0.35		
			4.0 V $\le V_{OUT(S)} \le$ 4.4 V	–	0.19	0.30		
			4.5 V $\le V_{OUT(S)} \le$ 4.9 V	–	0.18	0.27		
			5.0 V $\le V_{OUT(S)} \le$ 5.4 V	–	0.16	0.25		
			5.5 V $\le V_{OUT(S)} \le$ 6.0 V	–	0.15	0.23		
Line regulation 1	ΔV_{OUT1}	$V_{OUT(S)}+1$ V $\le V_{IN} \le 10$ V, I_{OUT} = 1 mA		–	5	20	mV	
Line regulation 2	ΔV_{OUT2}	$V_{OUT(S)}+1$ V $\le V_{IN} \le 10$ V, I_{OUT} = 1 µA		–	5	20		
Load regulation	ΔV_{OUT3}	$V_{IN}=V_{OUT(S)}+2$ V	1.1 V $\le V_{OUT(S)} \le$ 1.9 V, 1 µA $\le I_{OUT} \le$ 10 mA	–	5	20		
			2.0 V $\le V_{OUT(S)} \le$ 2.9 V, 1 µA $\le I_{OUT} \le$ 20 mA	–	10	30		
			3.0 V $\le V_{OUT(S)} \le$ 3.9 V, 1 µA $\le I_{OUT} \le$ 30 mA	–	20	45		
			4.0 V $\le V_{OUT(S)} \le$ 4.9 V, 1 µA $\le I_{OUT} \le$ 40 mA	–	25	65		
			5.0 V $\le V_{OUT(S)} \le$ 6.0 V, 1 µA $\le I_{OUT} \le$ 50 mA	–	35	80		
Output voltage temperature coefficient *4	$\frac{\Delta V_{OUT}}{\Delta Ta \bullet V_{OUT}}$	$V_{IN} = V_{OUT(S)} + 1$ V, I_{OUT} = 10 mA, $-40°C \le Ta \le 85°C$		–	±100	–	ppm /°C	
Current consumption	I_{SS}	$V_{IN} = V_{OUT(S)} + 2$ V, no load		–	1.2	2.5	µA	2
Input voltage	V_{IN}	–		–	–	10	V	1
Short current limit	I_{OS}	$V_{IN} = V_{OUT(S)} + 2$ V, V_{OUT} pin = 0 V		–	40	–	mA	3

***1.** $V_{OUT(S)}$: Specified output voltage
$V_{OUT(E)}$: Effective output voltage
i.e., the output voltage when fixing I_{OUT}(=10 mA) and inputting $V_{OUT(S)}+2.0$ V.

***2.** Output current at which output voltage becomes 95% of $V_{OUT(E)}$ after gradually increasing output current.

***3.** $V_{drop} = V_{IN1}-(V_{OUT(E)} \times 0.98)$, where V_{IN1} is the Input voltage at which output voltage becomes 98% of $V_{OUT(E)}$ after gradually decreasing input voltage.

***4.** Temperature change ratio for the output voltage [mV/°C] is calculated using the following equation.

$$\frac{\Delta V_{OUT}}{\Delta Ta}\left[mV/°C\right]^{*1} = V_{OUT(S)}\left[V\right]^{*2} \times \frac{\Delta V_{OUT}}{\Delta Ta \bullet V_{OUT}}\left[ppm/°C\right]^{*3} \div 1000$$

***1.** Temperature change ratio of the output voltage
***2.** Specified output voltage
***3.** Output voltage temperature coefficient

2. S-817B series

Table 10

(Ta=25°C unless otherwise specified)

Item	Symbol	Conditions		Min.	Typ.	Max.	Units	Measur-ement circuits
Output voltage *1	$V_{OUT(E)}$	$V_{IN}=V_{OUT(S)}+2$ V, $I_{OUT}=10$ mA		$V_{OUT(S)} \times 0.98$	$V_{OUT(S)}$	$V_{OUT(S)} \times 1.02$	V	1
Output current *2	I_{OUT}	$V_{OUT(S)}+2$ V $\le V_{IN} \le 10$ V	1.1 V $\le V_{OUT(S)} \le$ 1.9 V	20	–	–	mA	3
			2.0 V $\le V_{OUT(S)} \le$ 2.9 V	35	–	–		
			3.0 V $\le V_{OUT(S)} \le$ 3.9 V	50	–	–		
			4.0 V $\le V_{OUT(S)} \le$ 4.9 V	65	–	–		
			5.0 V $\le V_{OUT(S)} \le$ 6.0 V	75	–	–		
Dropout voltage *3	V_{drop}	I_{OUT} = 10 mA	1.1 V $\le V_{OUT(S)} \le$ 1.4 V	–	0.92	1.58	V	1
			1.5 V $\le V_{OUT(S)} \le$ 1.9 V	–	0.58	0.99		
			2.0 V $\le V_{OUT(S)} \le$ 2.4 V	–	0.40	0.67		
			2.5 V $\le V_{OUT(S)} \le$ 2.9 V	–	0.31	0.51		
			3.0 V $\le V_{OUT(S)} \le$ 3.4 V	–	0.25	0.41		
			3.5 V $\le V_{OUT(S)} \le$ 3.9 V	–	0.22	0.35		
			4.0 V $\le V_{OUT(S)} \le$ 4.4 V	–	0.19	0.30		
			4.5 V $\le V_{OUT(S)} \le$ 4.9 V	–	0.18	0.27		
			5.0 V $\le V_{OUT(S)} \le$ 5.4 V	–	0.16	0.25		
			5.5 V $\le V_{OUT(S)} \le$ 6.0 V	–	0.15	0.23		
Line regulation 1	ΔV_{OUT1}	$V_{OUT(S)}+1$ V $\le V_{IN} \le 10$ V, I_{OUT} = 1 mA		–	5	20	mV	
Line regulation 2	ΔV_{OUT2}	$V_{OUT(S)}+1$ V $\le V_{IN} \le 10$ V, I_{OUT} = 1 μA		–	5	20		
Load regulation	ΔV_{OUT3}	$V_{IN}=V_{OUT(S)}+2$ V	1.1 V $\le V_{OUT(S)} \le$ 1.9 V, 1 μA $\le I_{OUT} \le$ 10 mA	–	5	20		
			2.0 V $\le V_{OUT(S)} \le$ 2.9 V, 1 μA $\le I_{OUT} \le$ 20 mA	–	10	30		
			3.0 V $\le V_{OUT(S)} \le$ 3.9 V, 1 μA $\le I_{OUT} \le$ 30 mA	–	20	45		
			4.0 V $\le V_{OUT(S)} \le$ 4.9 V, 1 μA $\le I_{OUT} \le$ 40 mA	–	25	65		
			5.0 V $\le V_{OUT(S)} \le$ 6.0 V, 1 μA $\le I_{OUT} \le$ 50 mA	–	35	80		
Output voltage temperature coefficient *4	$\frac{\Delta V_{OUT}}{\Delta Ta \bullet V_{OUT}}$	$V_{IN} = V_{OUT(S)} + 1$ V, I_{OUT} = 10 mA, −40°C $\le$ Ta $\le$ 85°C		–	±100	–	ppm /°C	
Current consumption	I_{SS}	$V_{IN} = V_{OUT(S)} + 2$ V, no load		–	1.2	2.5	μA	2
Input voltage	V_{IN}	–		–	–	10	V	1

***1.** $V_{OUT(S)}$: Specified output voltage
$V_{OUT(E)}$: Effective output voltage
i.e., the output voltage when fixing I_{OUT}(=10 mA) and inputting $V_{OUT(S)}+2.0$ V.

***2.** Output current at which output voltage becomes 95% of $V_{OUT(E)}$ after gradually increasing output current.

***3.** $V_{drop} = V_{IN1}-(V_{OUT(E)} \times 0.98)$, where V_{IN1} is the Input voltage at which output voltage becomes 98% of $V_{OUT(E)}$ after gradually decreasing input voltage.

***4.** Temperature change ratio for the output voltage [mV/°C] is calculated using the following equation.

$$\frac{\Delta V_{OUT}}{\Delta Ta}\left[\text{mV/°C}\right]^{*1} = V_{OUT(S)}\left[\text{V}\right]^{*2} \times \frac{\Delta V_{OUT}}{\Delta Ta \bullet V_{OUT}}\left[\text{ppm/°C}\right]^{*3} \div 1000$$

***1.** Temperature change ratio of the output voltage
***2.** Specified output voltage
***3.** Output voltage temperature coefficient

■ Measurement Circuits

1.

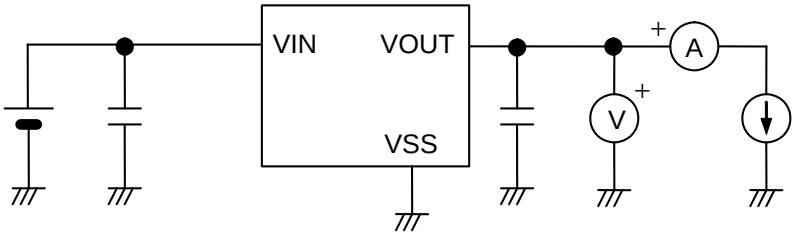


Figure 9

2.

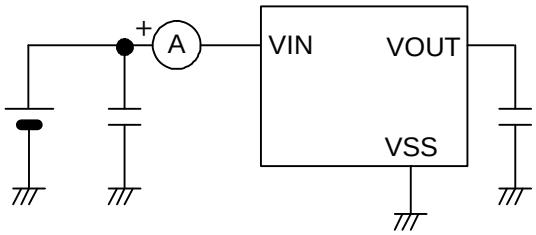


Figure 10

3.

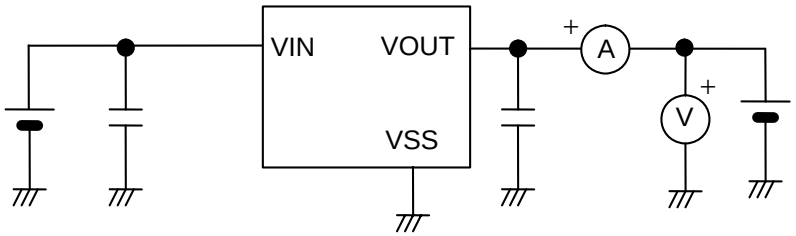
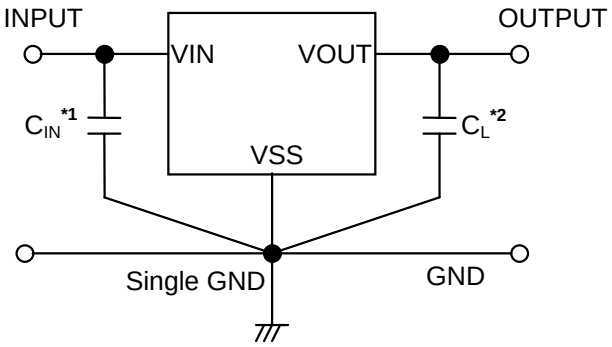


Figure 11

■ Standard Circuit



***1.** C_{IN} is a capacitor used to stabilize input.
***2.** In addition to tantalum capacitor, ceramic capacitor of 0.1 μF or more can be used for C_L.

Figure 12

Caution The above connection diagram and constant will not guarantee successful operation. Perform through evaluation using the actual application to set the constant.

■ Explanation of Terms

1. Low ESR

ESR is the abbreviation for Equivalent Series Resistance.
Low ESR output capacitors (C_L) can be used in the S-817 Series.

2. Output voltage (V_{OUT})

The accuracy of the output voltage is ±2.0% guaranteed under the specified conditions for input voltage, which differs depending upon the product items, output current, and temperature.

Caution If the above conditions change, the output voltage value may vary and go out of the accuracy range of the output voltage. See the electrical characteristics and characteristics data for details.

3. Line regulations 1 and 2 (ΔV_{OUT1}, ΔV_{OUT2})

Indicate the input voltage dependencies of output voltage. That is, the values show how much the output voltage changes due to a change in the input voltage with the output current remained unchanged.

4. Load regulation (ΔV_{OUT3})

Indicates the output current dependencies of output voltage. That is, the values show how much the output voltage changes due to a change in the output current with the input voltage remained unchanged.

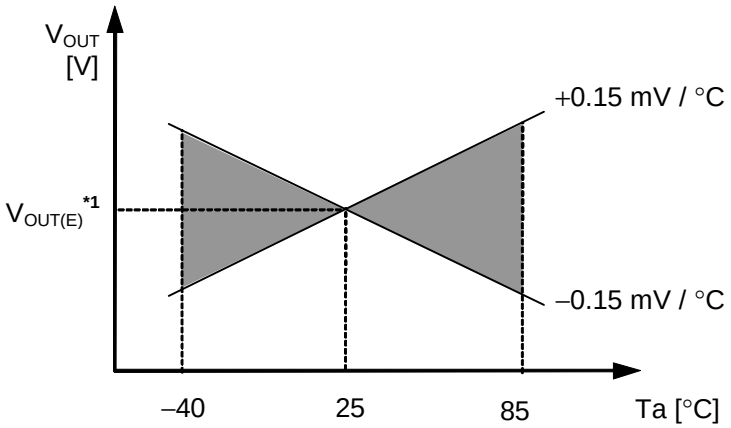
5. Dropout voltage (V_{drop})

Indicates a difference between input voltage (V_{IN1}) and output voltage when output voltage falls by 98% of $V_{OUT(E)}$ by gradually decreasing the input voltage (V_{IN}).
$V_{drop} = V_{IN1} - [V_{OUT(E)} \times 0.98]$

6. Temperature coefficient of output voltage $\left(\frac{\Delta V_{OUT}}{\Delta Ta \bullet V_{OUT}}\right)$

The shadowed area in **Figure 13** is the range where V_{OUT} varies in the operating temperature range when the temperature coefficient of the output voltage is ±100 ppm/°C.

Ex. S-817A15 Typ.



***1.** $V_{OUT(E)}$ is the value of the output voltage measured at 25°C.

Figure 13

A change in the temperature of the output voltage [mV/°C] is calculated using the following equation.

$$\frac{\Delta V_{OUT}}{\Delta Ta}[\text{mV/°C}]^{*1} = V_{OUT(S)}[\text{V}]^{*2} \times \frac{\Delta V_{OUT}}{\Delta Ta \bullet V_{OUT}}[\text{ppm/°C}]^{*3} \div 1000$$

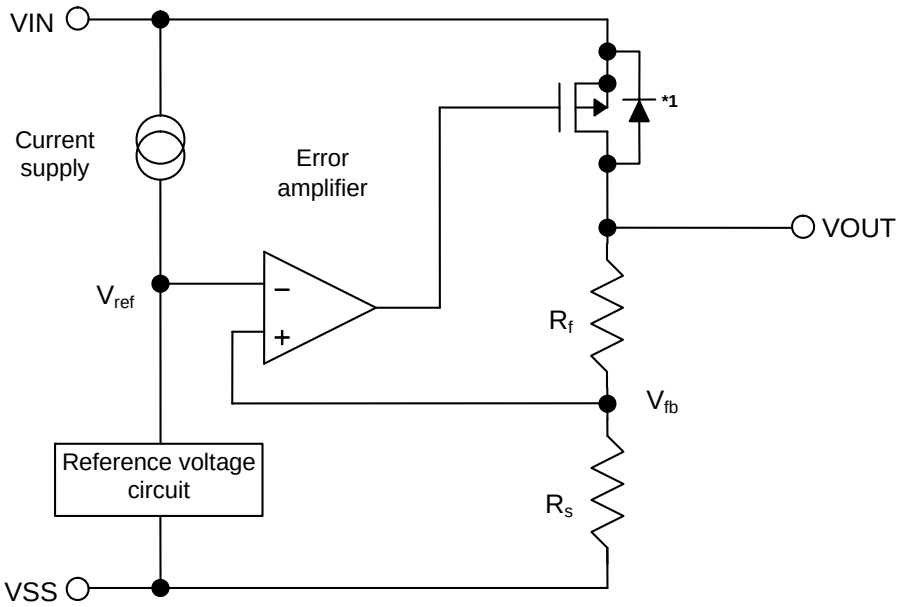
***1.** Change in temperature of output voltage
***2.** Specified output voltage
***3.** Output voltage temperature coefficient

■ Operation

1. Basic Operation

Figure 14 shows the block diagram of the S-817 Series.

The error amplifier compares the reference voltage (V_{ref}) with V_{fb}, which is the output voltage resistance-divided by feedback resistors R_s and R_f. It supplies the output transistor with the gate voltage necessary to ensure a certain output voltage free of any fluctuations of input voltage and temperature.



***1.** Parasitic diode

Figure 14

2. Output Transistor

The S-817 series uses a P-channel MOS FET as the output transistor.
Be sure that V_{OUT} does not exceed V_{IN}+0.3 V to prevent the voltage regulator from being damaged due to inverse current flowing from VOUT pin through a parastic diode to VIN pin.

3. Short Circuit Protection

The S-817A series incorporates a short circuit protection to protect the output transistor against short circuit between VOUT pin and VSS pin. Installation of the short-circuit protection which protects the output transistor against short-circuit between VOUT and VSS can be selected in the S-817A series. The short-circuit protection controls output current as shown in the "**Typical Characteristics 1.**". Output Voltage versus Output Current, and suppresses output current at about 40 mA even if VOUT and VSS pins are short-circuited.
The short-circuit protection can not be a thermal protection at the same time. Attention should be paid to the Input voltage and the load current under the actual condition so as not to exceed the power dissipation of the package including the case for short-circuit.
When the output current is large and the difference between input and output voltage is large even if not shorted, the short-circuit protection may work and the output current is suppressed to the specified value. For details, refer to "■ **Characteristics (Typical Data) 3. Maximum Output Current vs. Input Voltage**".
In addition, S-817B series is removing a short-circuit protection, and is the product which enabled it to pass large current.

■ Selection of Output Capacitor (C_L)

To stabilize operation against variation in output load, a capacitor (C_L) must be mounted between VOUT and VSS in the S-817 series because the phase is compensated with the help of the internal phase compensation circuit and the ESR of the output capacitor.

When selecting a ceramic or an OS capacitor, capacitance should be 0.1 μF or more, and when selecting a tantalum or an aluminum electrolytic capacitor, capacitance should be 0.1 μF or more and ESR 30 Ω or less.

When an aluminum electrolytic capacitor is used attention should be especially paid to since the ESR of the aluminum electrolytic capacitor increases at low temperature and possibility of oscillation becomes large. Sufficient evaluation including temperature characteristics is indispensable. Overshoot and undershoot characteristics differ depending upon the type of the output capacitor. Refer to C_L dependencies in "■ **Reference Data 1. Transient Response Characteristics**".

■ Application Circuits

1. Output Current Boosting Circuit

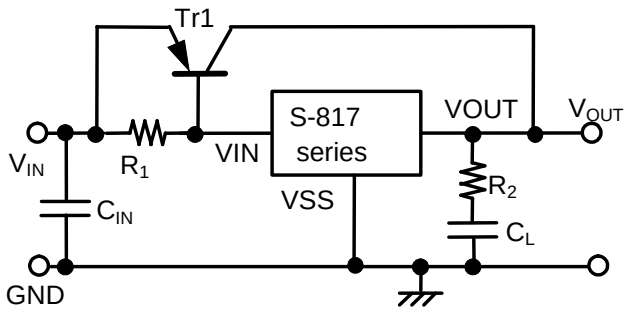


Figure 15

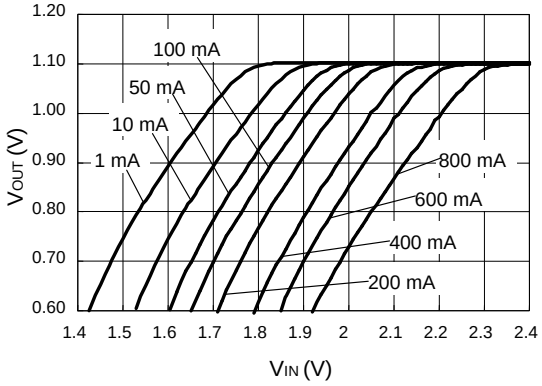
As shown in **Figure 15**, the output current can be boosted by externally attaching a PNP transistor. The base current of the PNP transistor is controlled so that output voltage (V_{OUT}) goes the voltage specified in the S-817 Series when base-emitter voltage (V_{BE}) necessary to turn on the PNP transistor is obtained between input voltage (V_{IN}) and S-817 Series power source pin (VIN).
The following are tips and hints for selecting and ensuring optimum use of external parts

- PNP transistor (Tr1):
  1. Set h_{FE} to approx. 100 to 400.
  2. Confirm that no problem occurs due to power dissipation under normal operation conditions.
- Resistor (R_1):
  Generally set R_1 to 1 kΩ ÷ $V_{OUT\,(S)}$ (the voltage specified in the S-817 Series) or more.
- Output capacitor (C_L):
  Output capacitor (C_L) is effective in minimizing output fluctuation at powering on or due to power or load fluctuation, but oscillation might occur. Always connect resistor R2 in series to output capacitor C_L.
- Resistor (R_2): Set R_2 to 2 Ω × $V_{OUT(S)}$ or more.
- DO NOT attach a capacitor between the S-817 Series power source (V_{IN}) and GND pins or between base and emitter of the PNP transistor to avoid oscillation.
- To improve transient response characteristics of the output current boosting circuit shown in **Figure 15**, check that no problem occurs due to output fluctuation at powering on or due to power or load fluctuation under normal operating conditions.
- Pay attention to the short current limit circuit incorporated into the S-817 Series because it does not function as a shortcircuiting protection circuit for this boosting circuit.

The following graphs show the examples of input-output voltage characteristics (Ta=25°C, typ.) in the output current boosting circuit as seen in **Figure 15**:

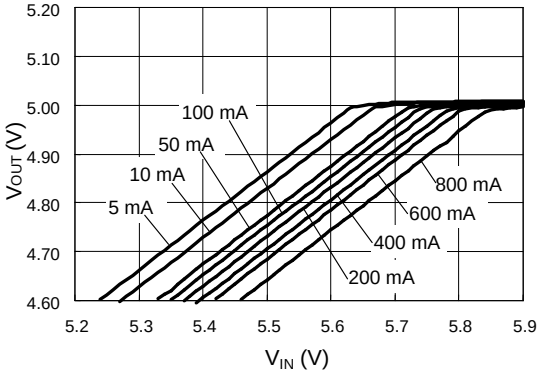
1. 1 S-817A11ANB/S-817B11AMC

Tr1 : 2SA1213Y, R_1 : 1 kΩ, C_L : 10 µF, R_2 : 2 Ω



1. 2 S-817A50ANB/S-817B50AMC

Tr1 : 2SA1213Y, R_1 : 200 Ω, C_L : 10 µF, R_2 : 10 Ω



2. Constant Current Circuit

2. 1 Constant Current Circuit

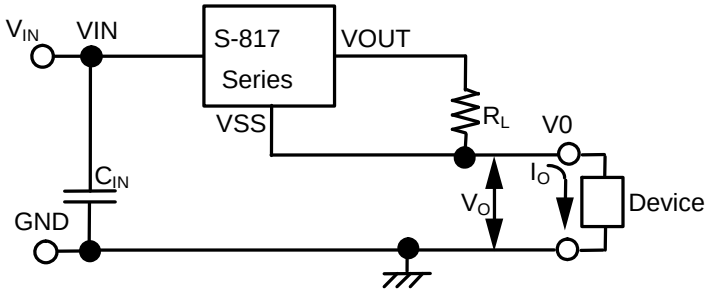


Figure 16

2. 2 Constant Current Boosting Circuit

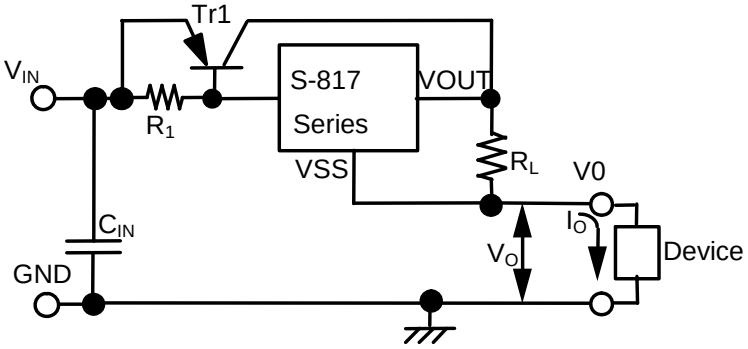


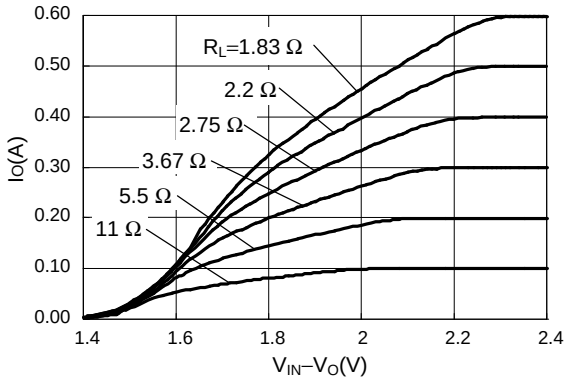
Figure 17

The S-817 Series can be configured as a constant current circuit. Refer to **Figure 16 and 17**. Constant amperage (I_O) is calculated using the following equation ($V_{OUT(E)}$: Effective output voltage): $I_O = (V_{OUT(E)} \div R_L) + I_{SS}$.

Note that by using a circuit in Figure16, it is impossible to set the better driving ability to the constant amperage (IO) than the S-817 Series basically has.
To gain the driving ability which exceeds the S-817 Series, there's a way to combine a constant current circuit and a current boosting circuit, as seen in Figure 17.
The maximum input voltage for a constant current circuit is 10 V + the voltage for device (VO).
It is not recommended to add a capacitor between the VIN (power supply) and VSS pin or the VOUT (output) and VSS pin because the rush current flows at power-on.
The following is a characteristics example of input voltage between VIN and VO vs. IO current (Typ. Ta = 25°C) in constant current boosting circuit in Figure 17.

V_{IN}, V_O pins, Input voltage - I_O current

S-817A11ANB, S-817B11AMC, Tr : 2SK1213Y, R_1 : 1 kΩ, V_O=2 V



3. Output Voltage Adjustment Circuit (Only for S-817B Series (Product without short circuit protection))

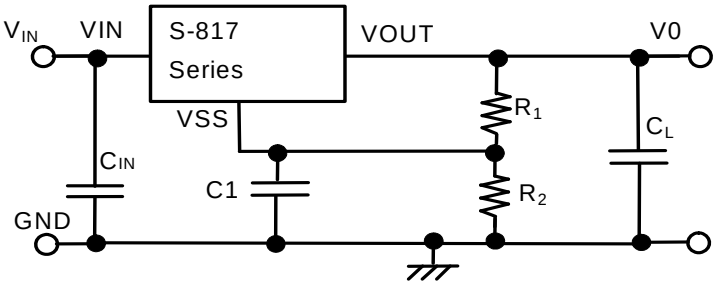


Figure 18

The output voltage can be boosted by using the configuration shown in **Figure 18**. The output Voltage (V_O) can be calculated using the following equation ($V_{OUT(E)}$:Effective output voltage):

$$V_O = V_{OUT(E)} \times (R_1 + R_2) \div R_1 + R_2 \times I_{SS}$$

Set the values of resistors R_1 and R_2 so that the S-817 Series is not affected by current consumption (I_{SS}).

Capacitor C1 is effective in minimizing output fluctuation at powering on or due to power or load fluctuation. Determine the optimum value on your actual device. But it is not also recommended to attach a capacitor between the S-817 Series power source VIN and VSS pin or between output VOUT and VSS pin because output fluctuation or oscillation at powering on might occur. As shown in **Figure 18**, a capacitor must be mounted between VIN and GND, and between VOUT and GND.

■ Precautions

- Wiring patterns for the VIN, VOUT and GND pins should be designed so that the impedance is low. When mounting an output capacitor between the VOUT and VSS pins (C_L) and a capacitor for stabilizing the input between VIN and VSS pins (C_{IN}), the distance from the capacitors to these pins should be as short as possible.
- Note that the output voltage may increase when a series regulator is used at low load current (1.0 μA or less).
- Generally a series regulator may cause oscillation, depending on the selection of external parts. The following conditions are recommended for this IC. However, be sure to perform sufficient evaluation under the actual usage conditions for selection, including evaluation of temperature characteristics.

  Output capacitor (C_L) : 0.1 μF or more
  Equivalent Series Resistance (ESR) : 30 Ω or less
  Input series resistance (R_{IN}) : 10 Ω or less

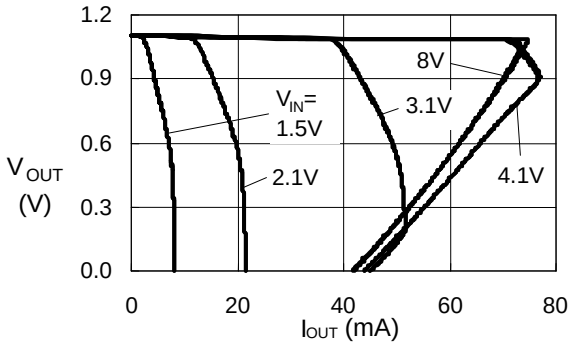
- The voltage regulator may oscillate when the impedance of the power supply is high and the input capacitor is small or an input capacitor is not connected.
- The application conditions for the input voltage, output voltage, and load current should not exceed the package power dissipation.
- Do not apply an electrostatic discharge to this IC that exceeds the performance ratings of the built-in electrostatic protection circuit.
- SII claims no responsibility for any disputes arising out of or in connection with any infringement by products including this IC of patents owned by a third party.

■ Characteristics (Typical Data)

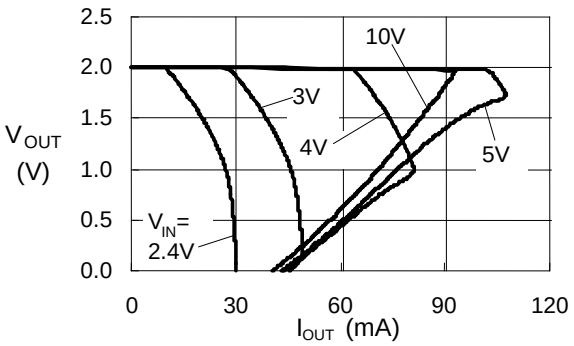
1. Output Voltage vs. Output Current (when load current increases)

(a) S-817A Series

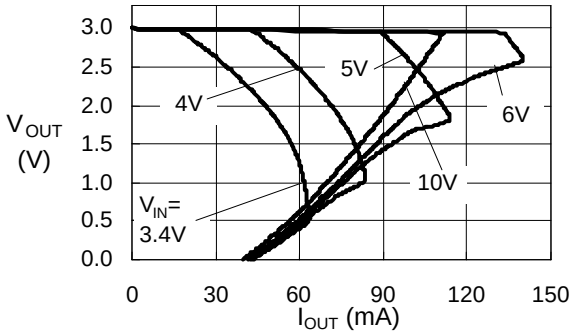
S-817A11A (Ta=25°C)



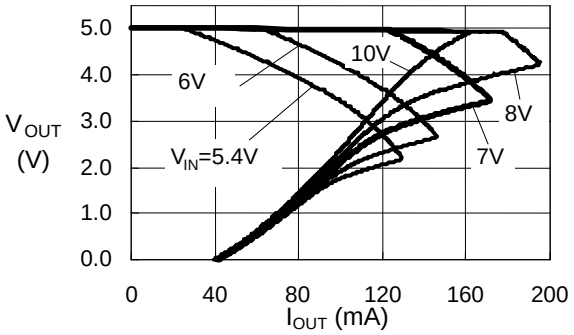
S-817A20A (Ta=25°C)



S-817A30A (Ta=25 °C)

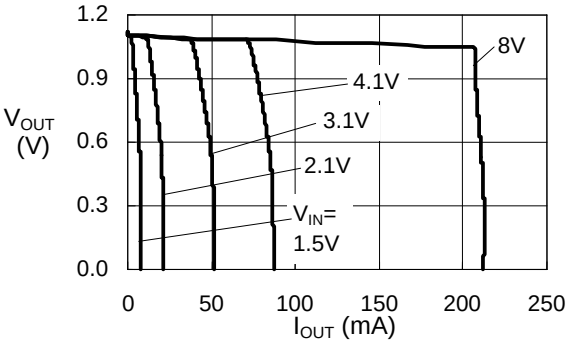


S-817A50A (Ta=25 °C)

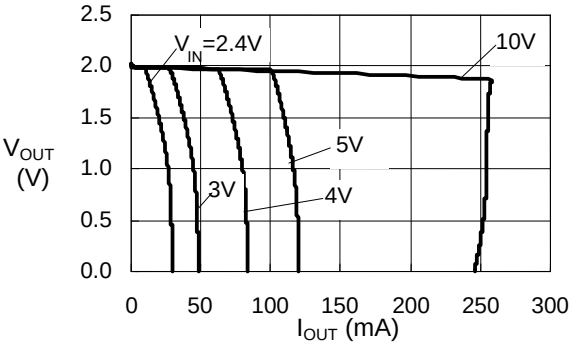


(b) S-817B series

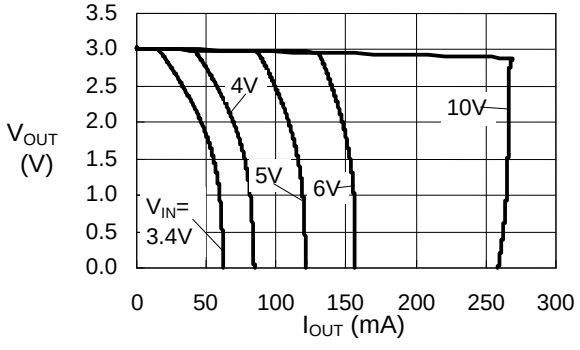
S-817B11A (Ta=25°C)



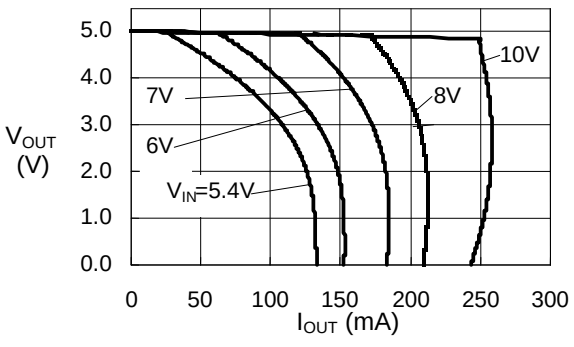
S-817B20A (Ta=25°C)



S-817B30A (Ta=25°C)

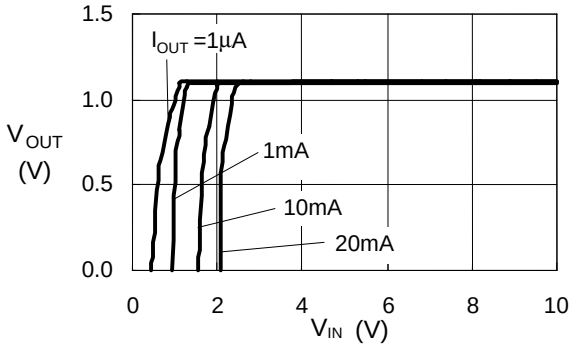


S-817B50A (Ta=25°C)

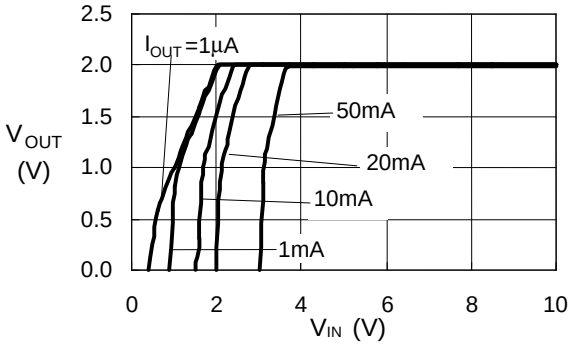


2. Output Voltage vs. Input Voltage

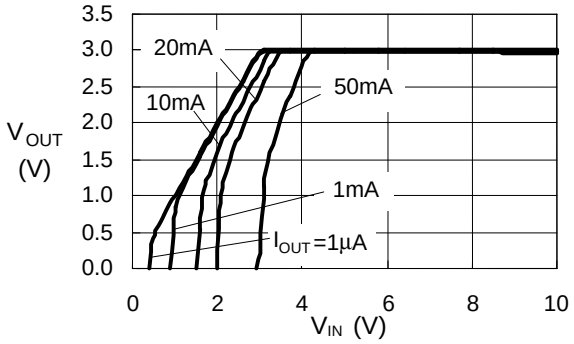
S-817A11A/S-817B11A (Ta=25°C)



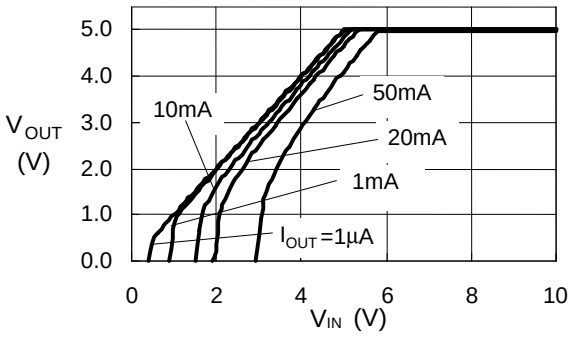
S-817A20A/S-817B20A (Ta=25°C)



S-817A30A/S-817B30A (Ta=25°C)



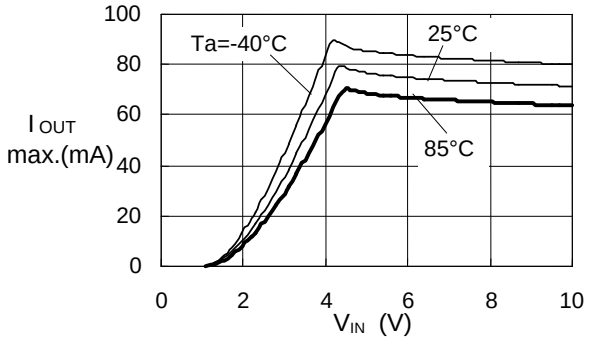
S-817A50A/S-817B50A (Ta=25°C)



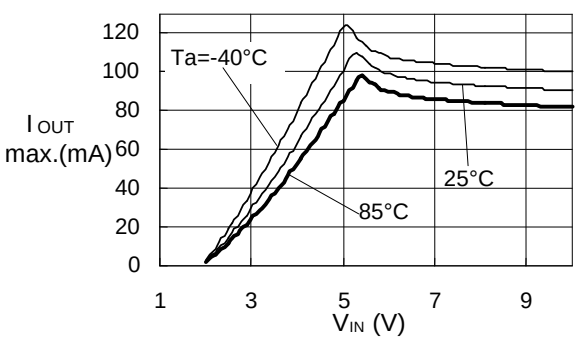
3. Maximum Output Current vs. Input Voltage

(a) S-817A Series

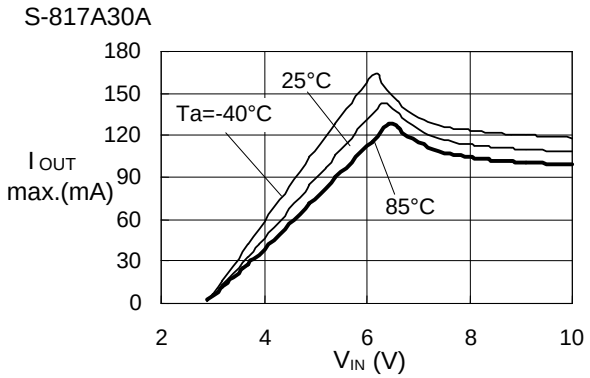
S-817A11A



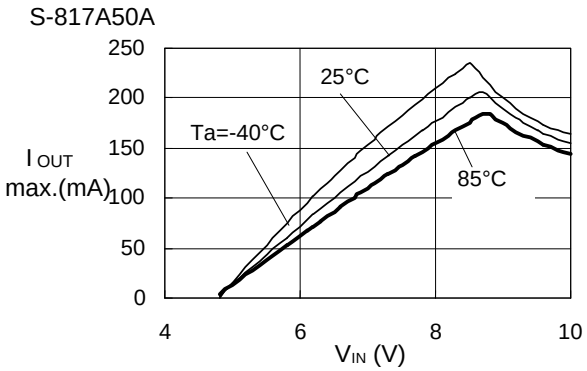
S-817A20A



S-817A30A

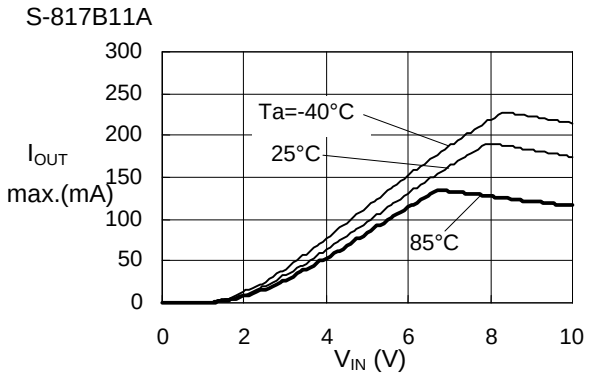


S-817A50A

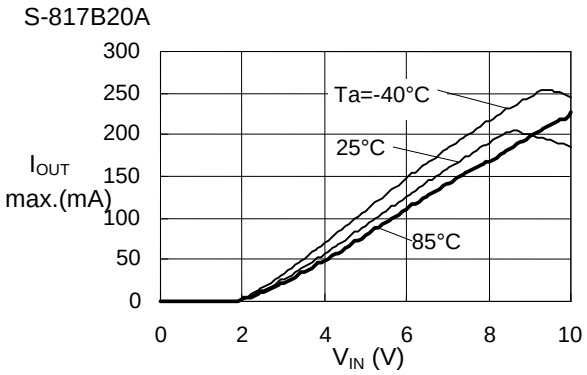


(b) S-817B Series

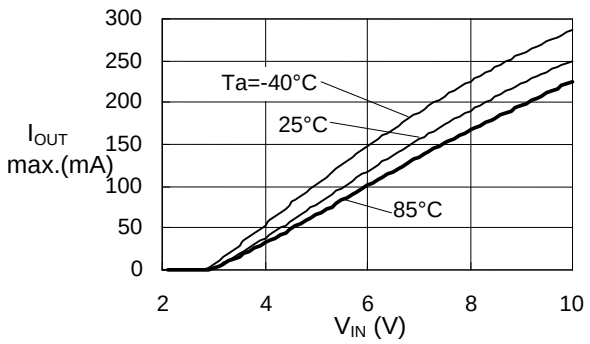
S-817B11A



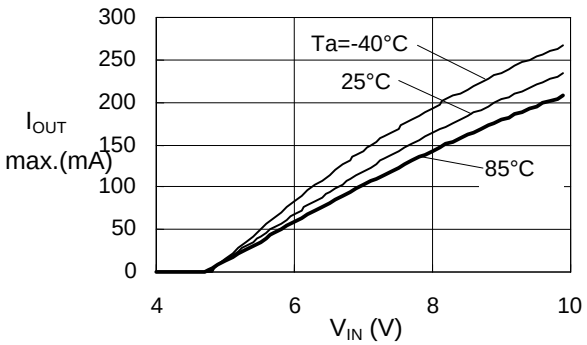
S-817B20A



S-817B30A

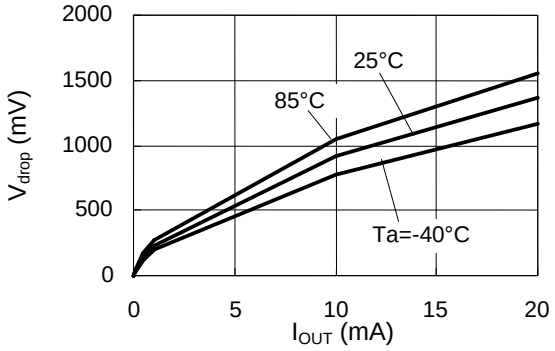


S-817B50A

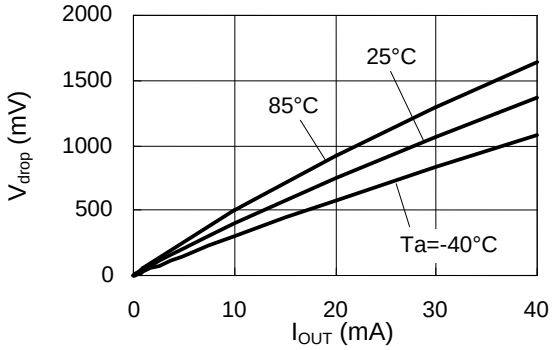


4. Dropout Voltage vs. Output Current

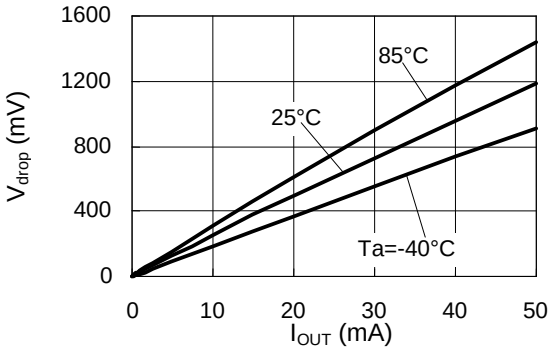
S-817A11A/S-817B11A



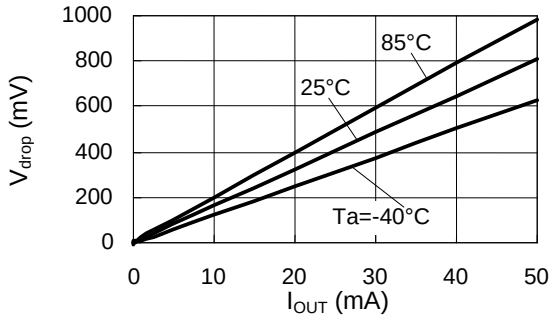
S-817A20A/S-817B20A



S-817A30A/S-817B30A

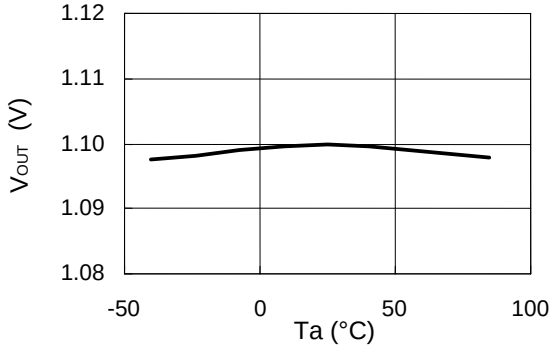


S-817A50A/S-817B50A

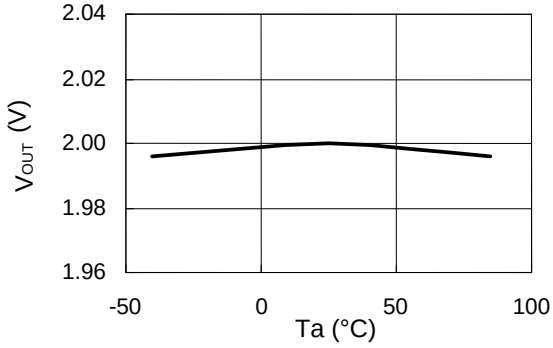


5. Output Voltage vs. Ambient Temperature

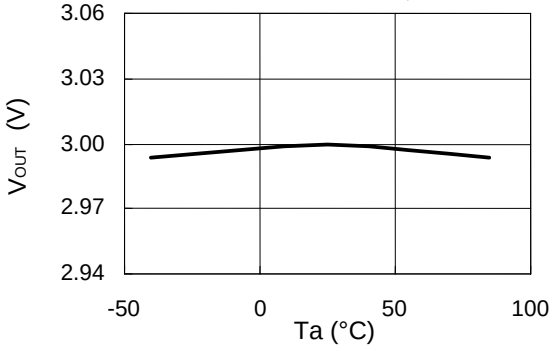
S-817A11A/S-817B11A V_{IN}=3.1V, I_{OUT}=10mA



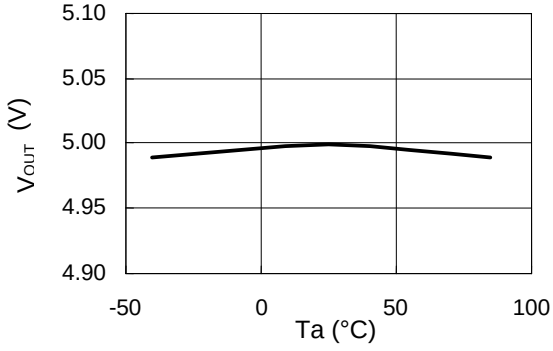
S-817A20A/S-817B20A V_{IN}=4V, I_{OUT}=10mA



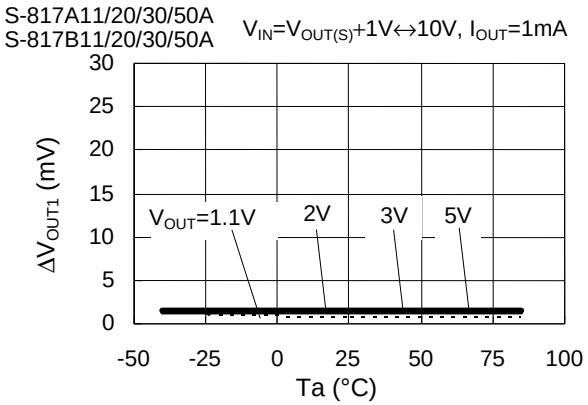
S-817A30A/S-817B30A V_{IN}=5V, I_{OUT}=10mA



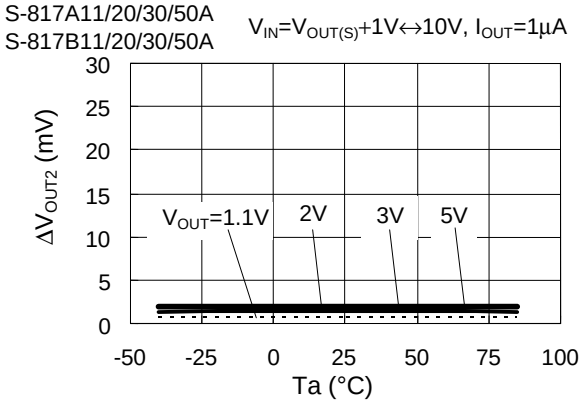
S-817A50A/S-817B50A V_{IN}=7V, I_{OUT}=10mA



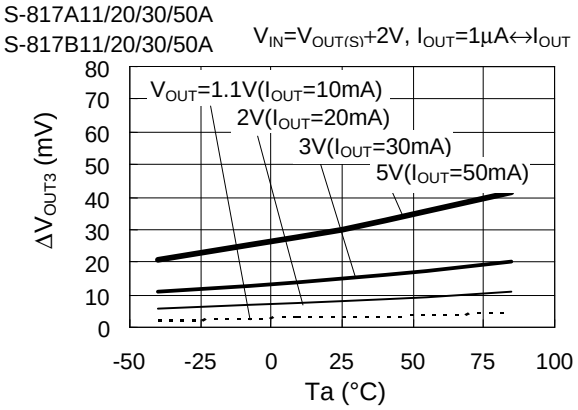
6. Line Regulation 1 vs. Ambient Temperature



7. Line Regulation 2 vs. Ambient Temperature

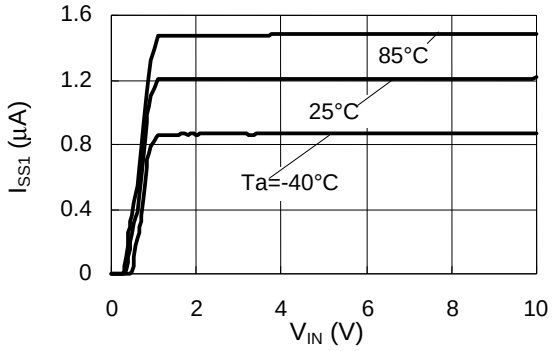


8. Load Regulation vs. Ambient Temperature

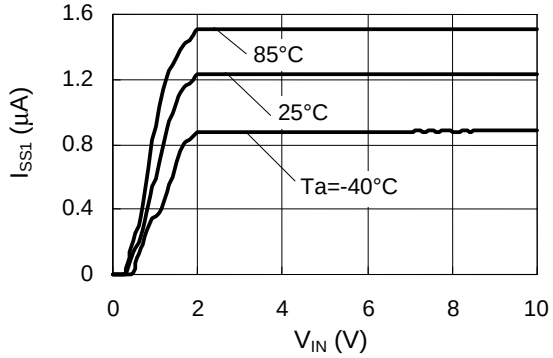


9. Current Consumption vs. Input Voltage

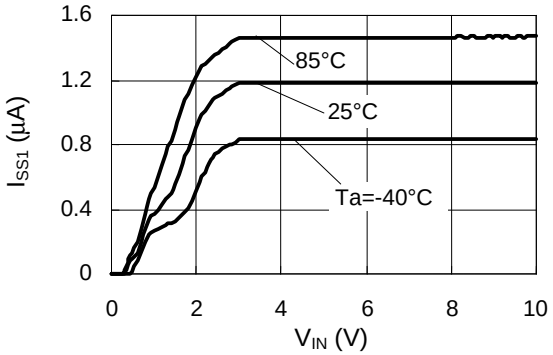
S-817A11A/S-817B11A



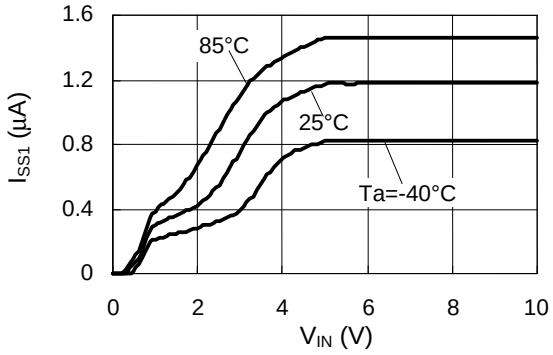
S-817A20A/S-817B20A



S-817A30A/S-817B30A

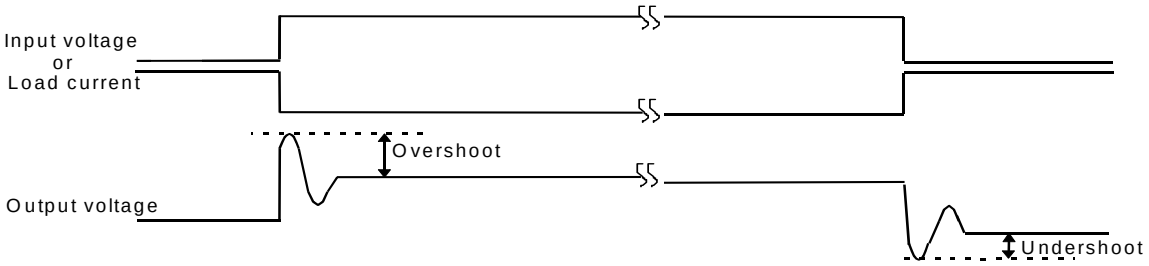


S-817A50A/S-817B50A

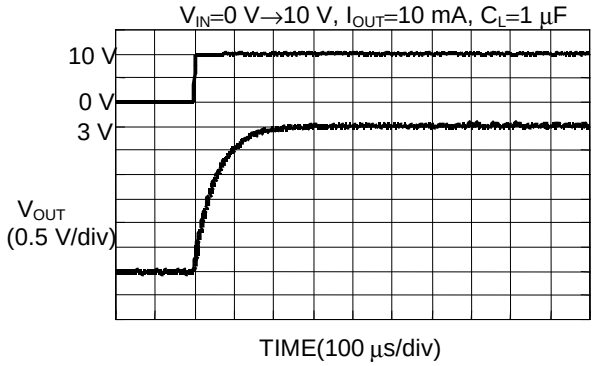


■ Reference Data

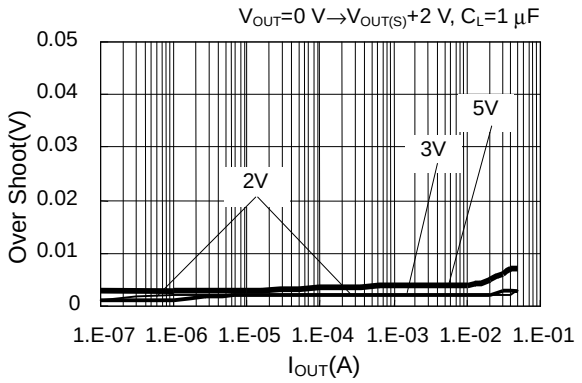
1. Transient Response Characteristics (Typical data: Ta=25 °C)



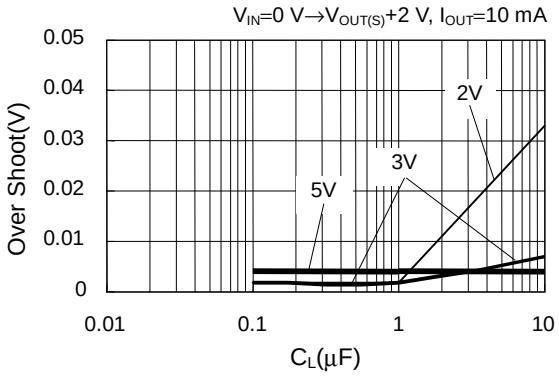
1. 1 At powering on S-817A30A (when using a ceramic capacitor, C_L=1 µF)



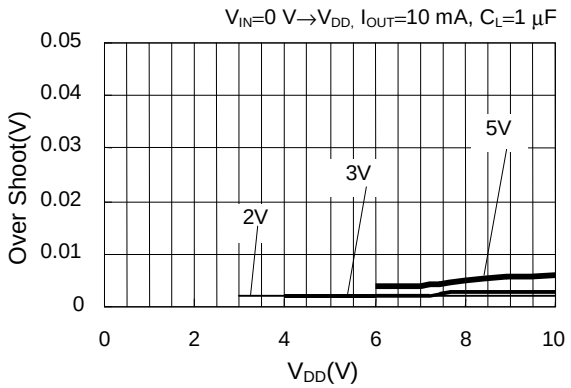
Load dependencies of overshoot at powering on



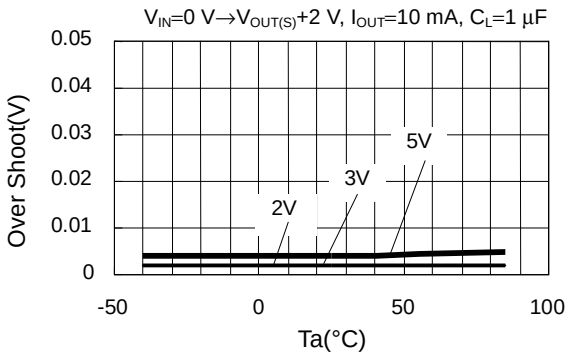
C_L dependencies of overshoot at powering on



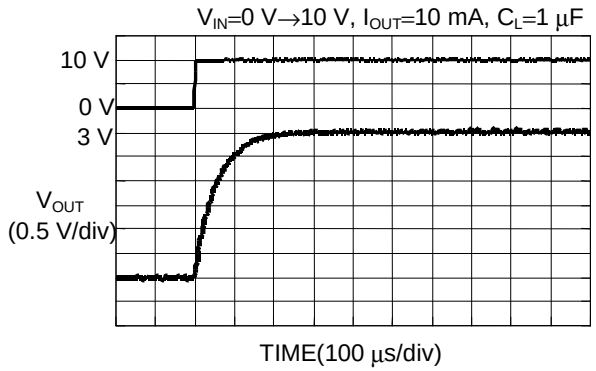
V_{DD} dependencies of overshoot at powering on



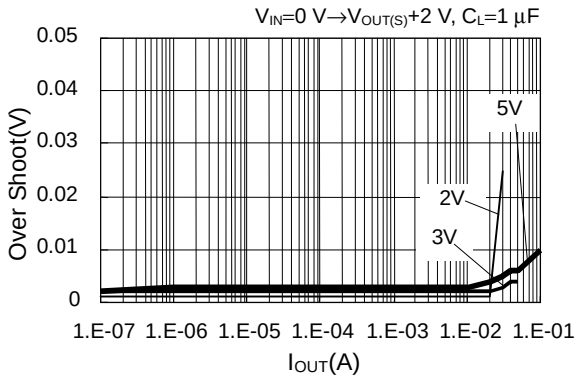
"Ta" dependencies of overshoot at powering on



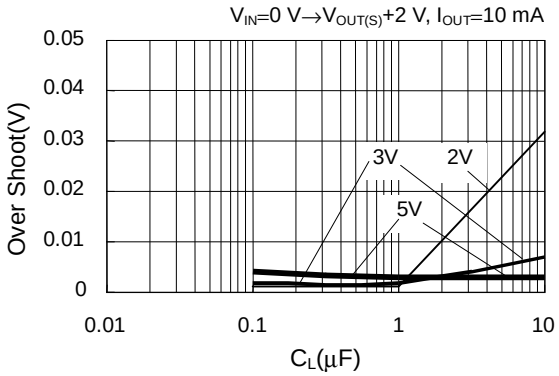
1. 2 At powering on S-817B30A (when using a ceramic capacitor, C_L=1 μF)



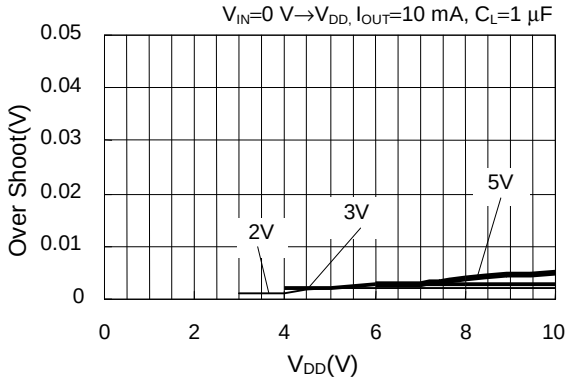
Load dependencies of overshoot at powering on



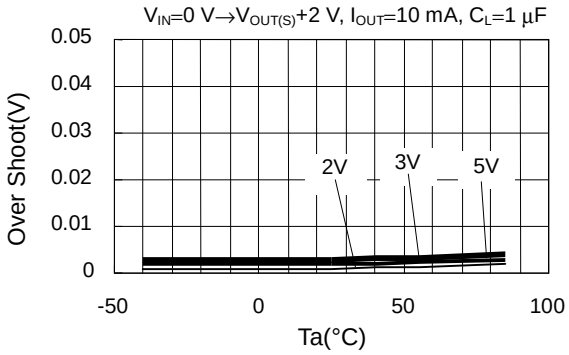
C_L dependencies of overshoot at powering on



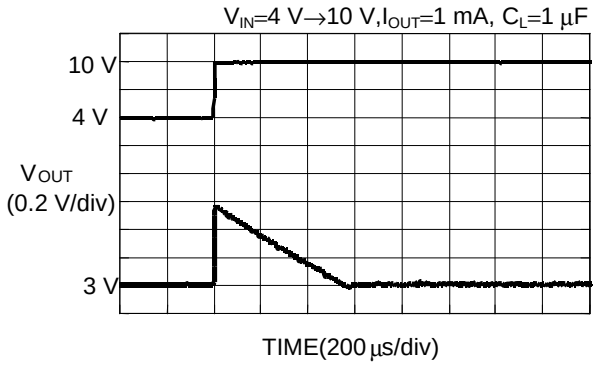
V_{DD} dependencies of overshoot at powering on



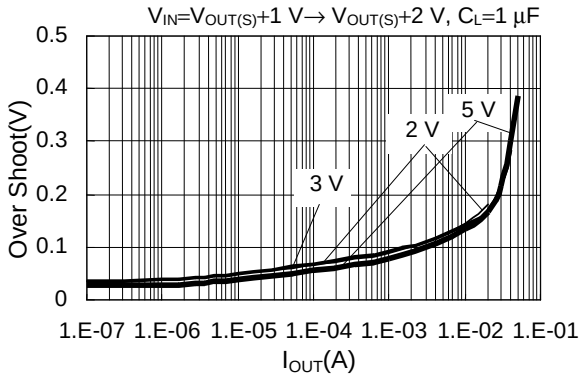
"Ta" dependencies of overshoot at powering on



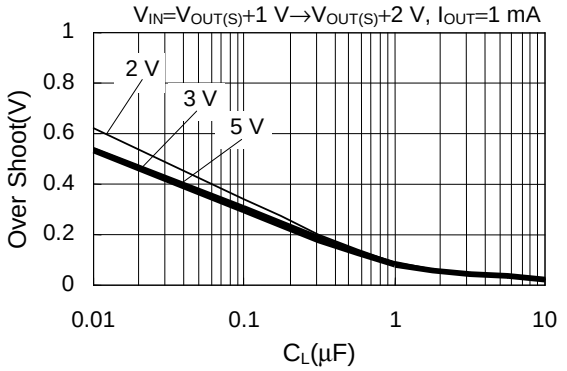
1. 3 Power fluctuation S-817A30A / S-817B30A (when using a ceramic capacitor, C_L=1 μF)



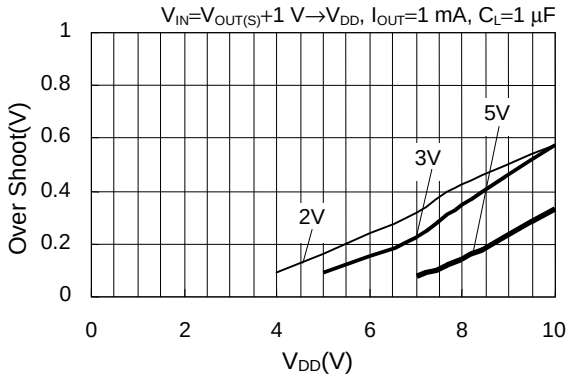
Load dependencies of overshoot at power fluctuation



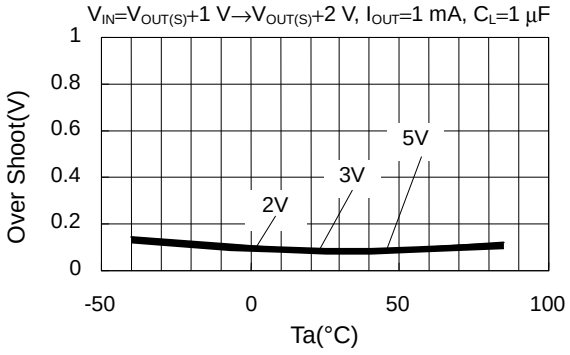
C_L dependencies of overshoot at power fluctuation

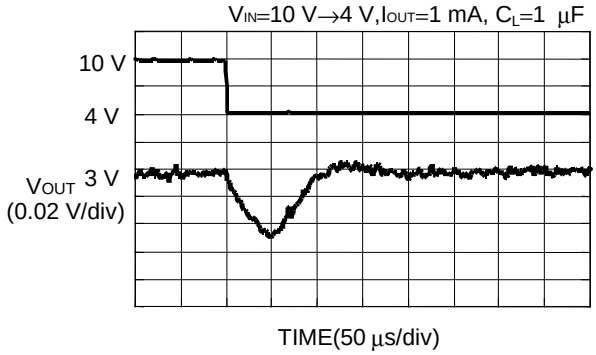


V_{DD} dependencies of overshoot at power fluctuation

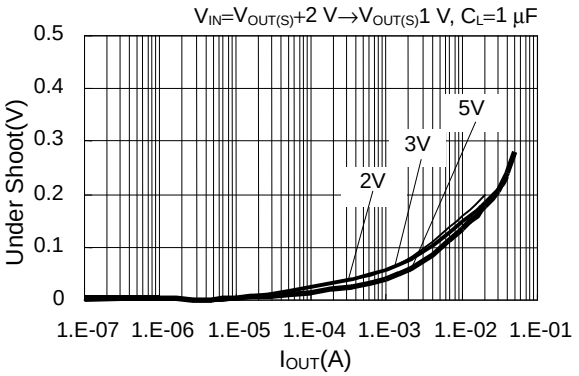


"Ta" dependencies of overshoot at power fluctuation

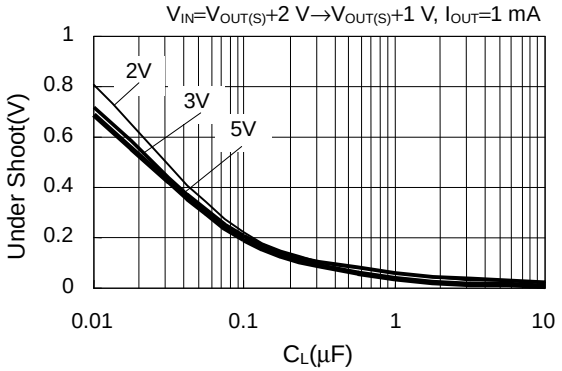




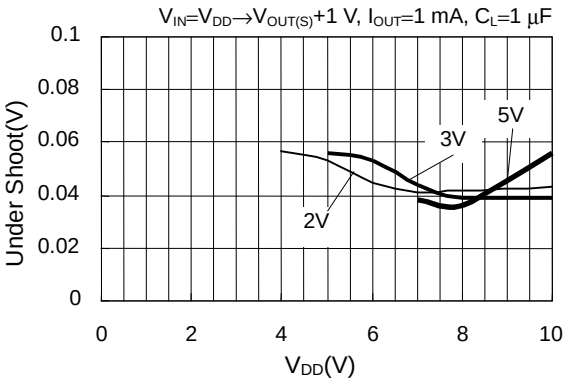
Load dependencies of undershoot at power fluctuation



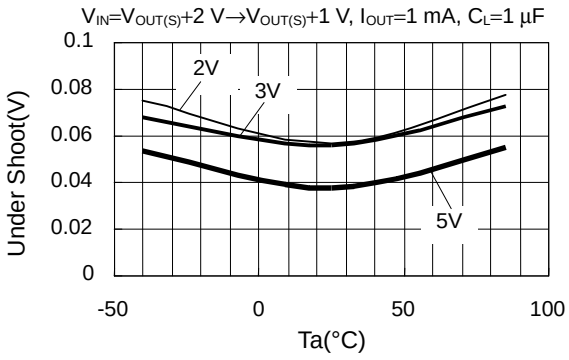
C_L dependencies of undershoot at power fluctuation



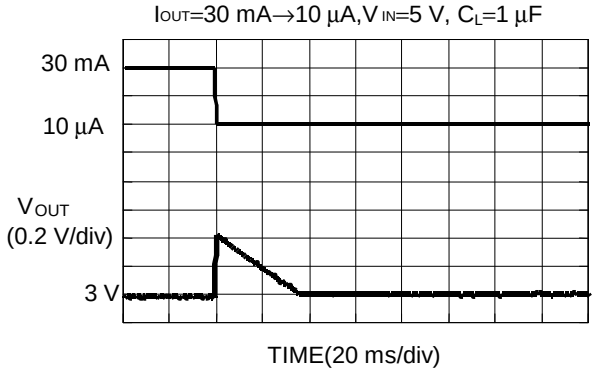
V_{DD} dependencies of undershoot at power fluctuation



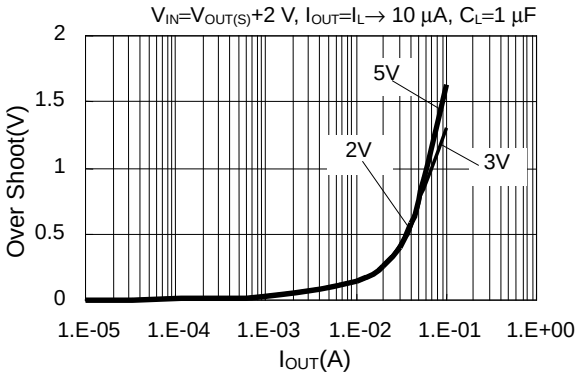
"Ta" dependencies of undershoot at power fluctuation



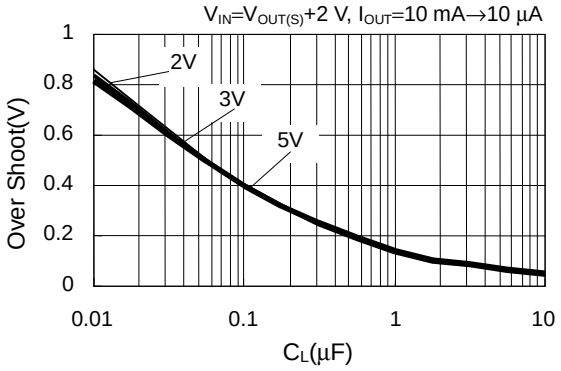
1. 4 Load fluctuation S-817A30A/S-817B30A (when using a ceramic capacitor, C_L=1 µF)



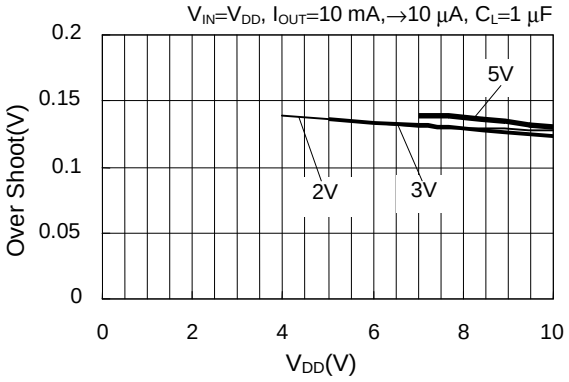
Load current dependencies of overshoot at load fluctuation



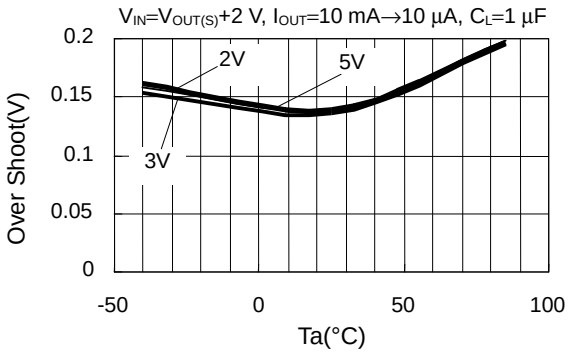
C_L dependencies of overshoot at load fluctuation

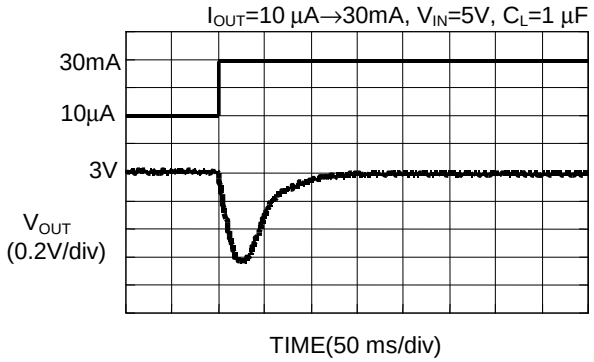


V_{DD} dependencies of overshoot at load fluctuation

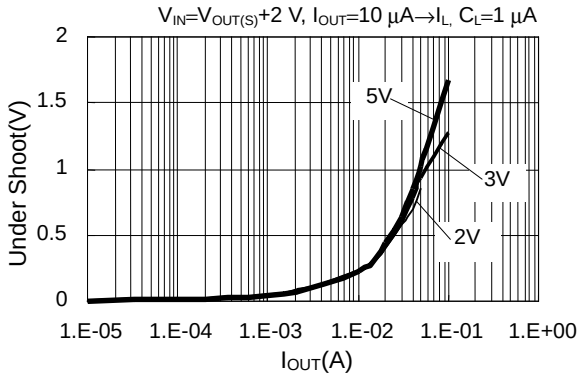


"Ta" dependencies of overshoot at load fluctuation

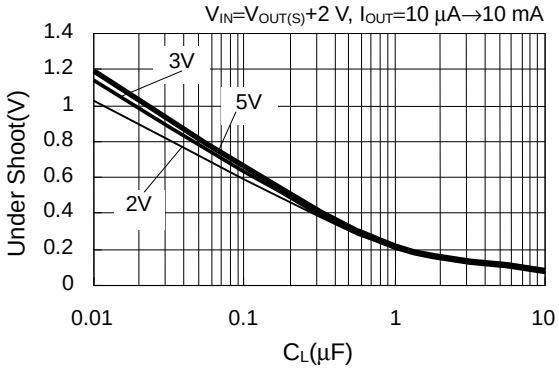




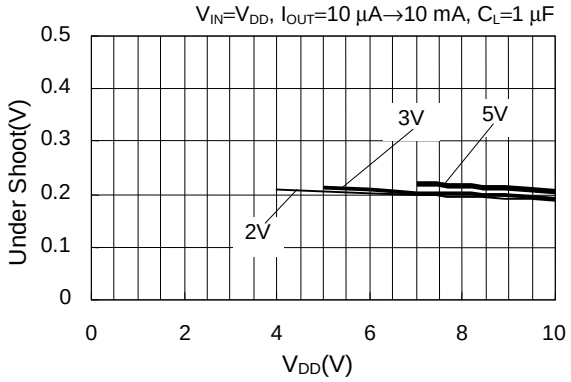
Load current dependencies of undershoot at load fluctuation



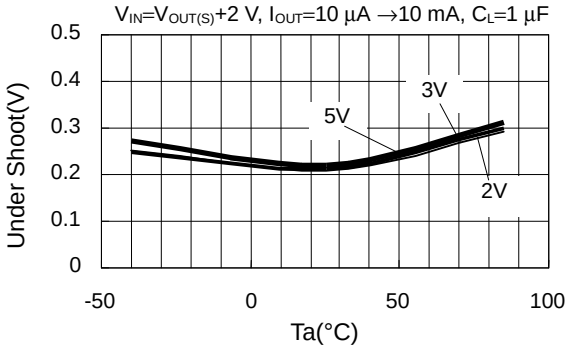
C_L dependencies of undershoot at load fluctuation

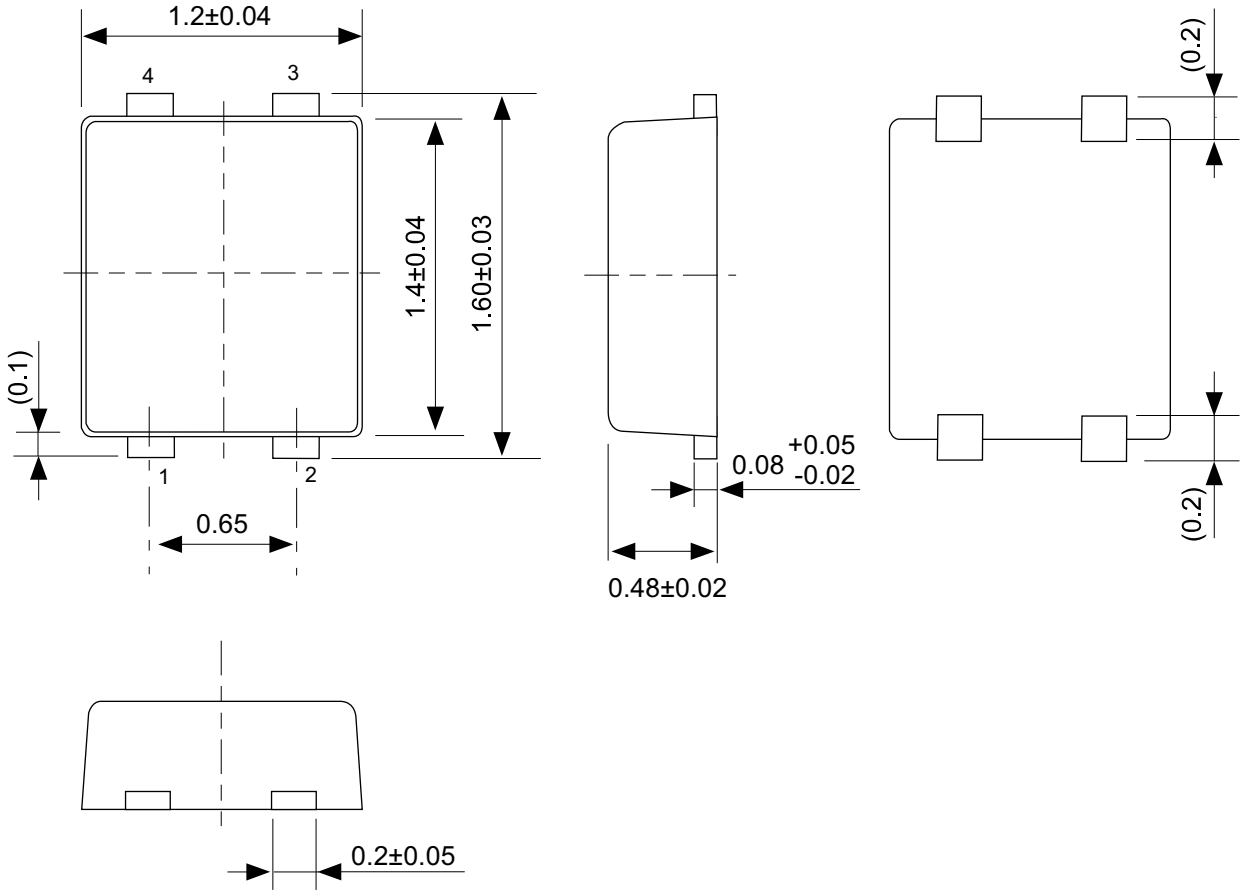


V_{DD} dependencies of undershoot at load fluctuation



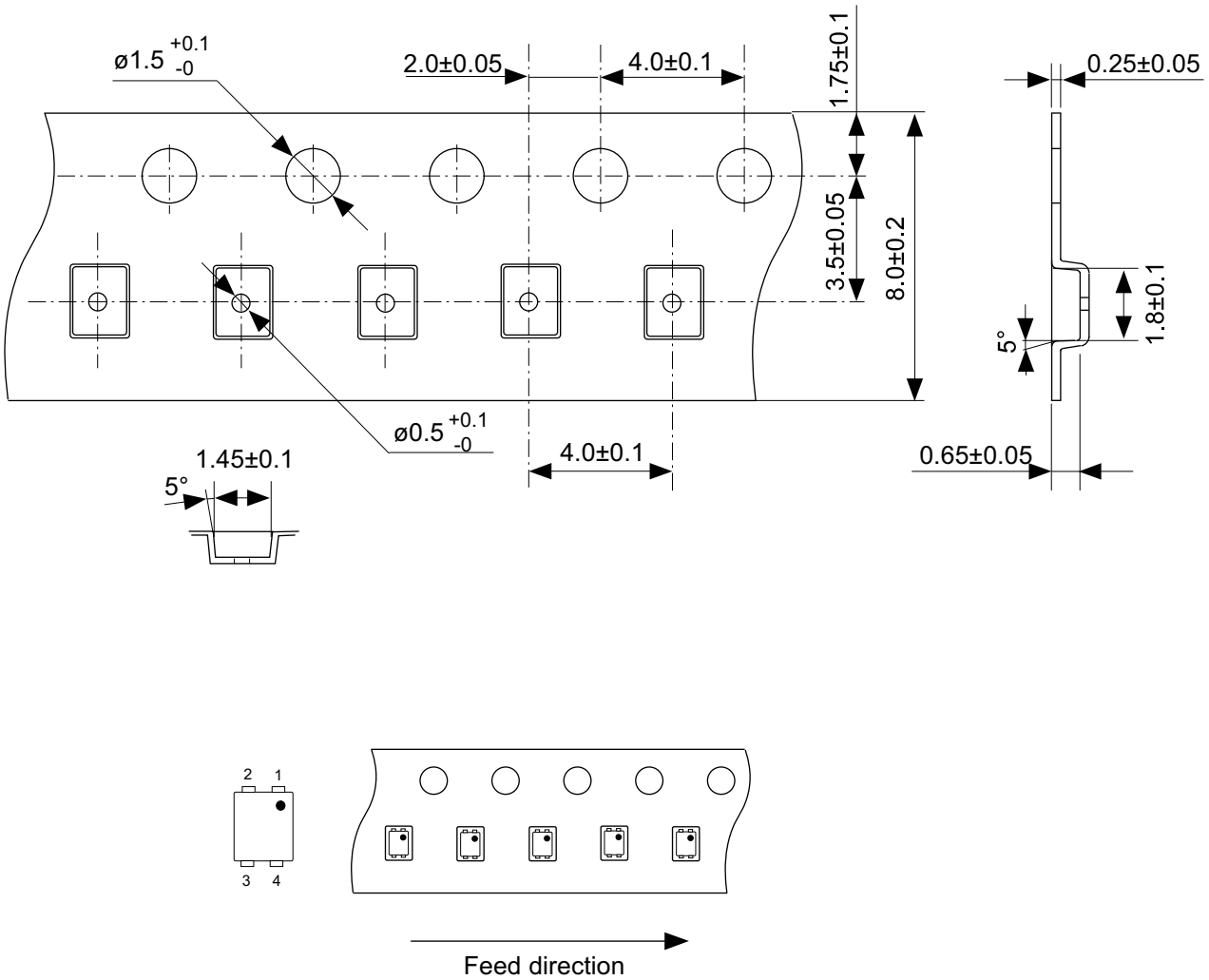
"Ta" dependencies of undershoot at load fluctuation





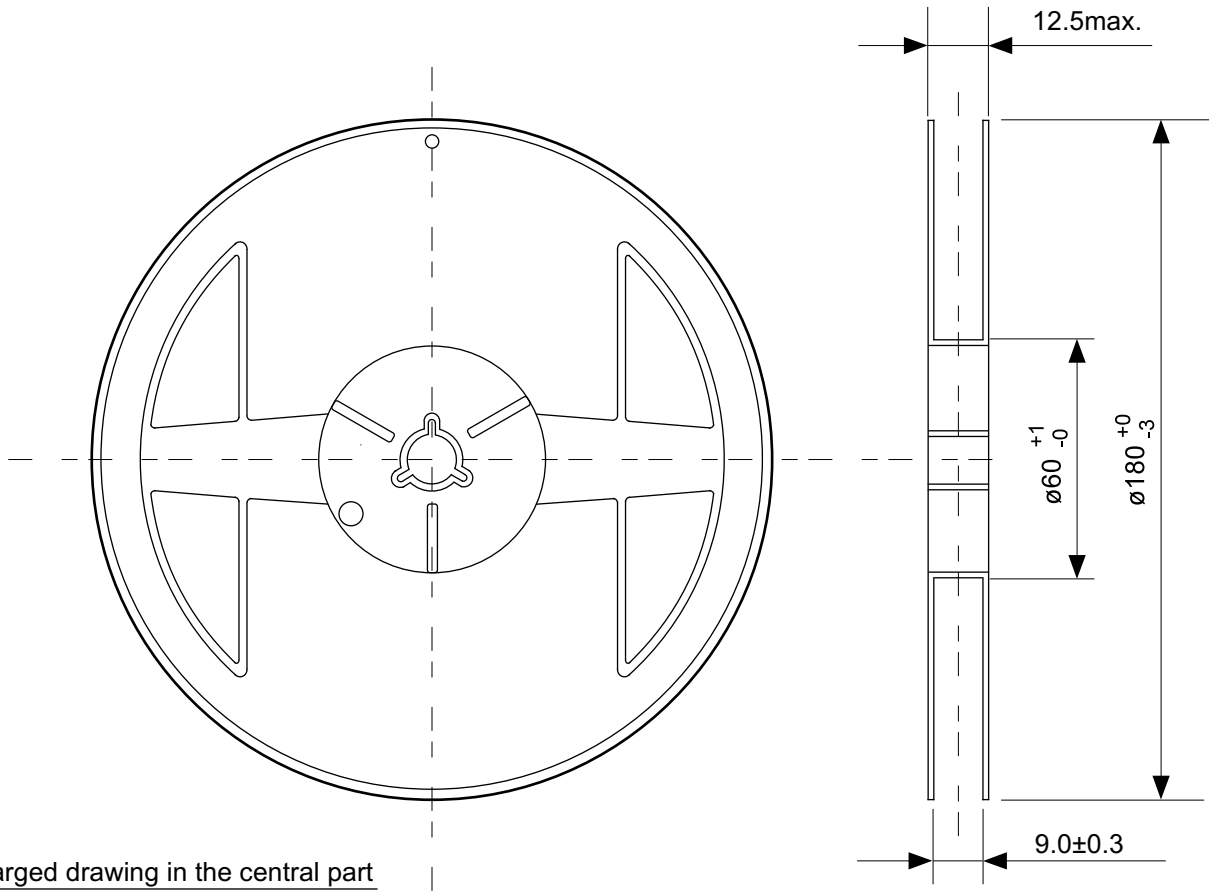
No. PF004-A-P-SD-4.0

TITLE	SNT-4A-A-PKG Dimensions
No.	PF004-A-P-SD-4.0
SCALE	
UNIT	mm
Seiko Instruments Inc.	

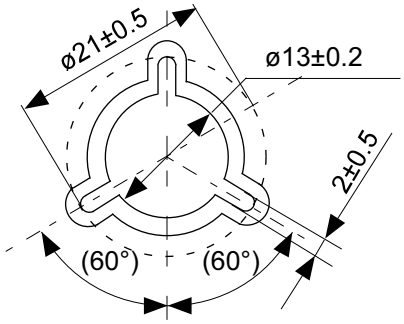


No. PF004-A-C-SD-1.0

TITLE	SNT-4A-A-Carrier Tape
No.	PF004-A-C-SD-1.0
SCALE	
UNIT	mm
Seiko Instruments Inc.	

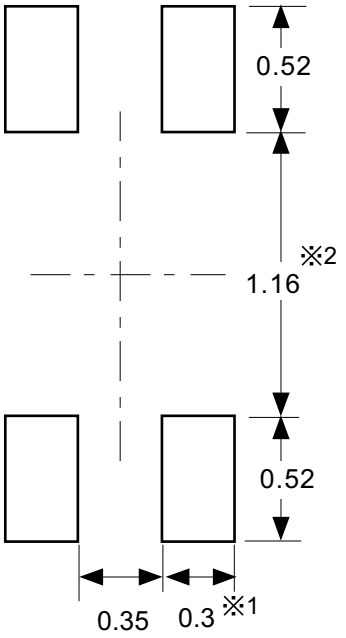


Enlarged drawing in the central part



No. PF004-A-R-SD-1.0

TITLE	SNT-4A-A-Reel		
No.	PF004-A-R-SD-1.0		
SCALE		QTY.	5,000
UNIT	mm		
Seiko Instruments Inc.			



※1. ランドパターンの幅に注意してください (0.25 mm min. / 0.30 mm typ.)。
※2. パッケージ中央にランドパターンを広げないでください (1.10 mm ~ 1.20 mm)。

注意 1. **パッケージのモールド樹脂下にシルク印刷やハンダ印刷などしないでください。**
2. **パッケージ下の配線上のソルダーレジストなどの厚みをランドパターン表面から0.03 mm 以下にしてください。**
3. **マスク開口サイズと開口位置はランドパターンと合わせてください。**
4. **詳細は"SNTパッケージ活用の手引き"を参照してください。**

※1. Pay attention to the land pattern width (0.25 mm min. / 0.30 mm typ.).
※2. Do not widen the land pattern to the center of the package (1.10 mm to 1.20 mm).

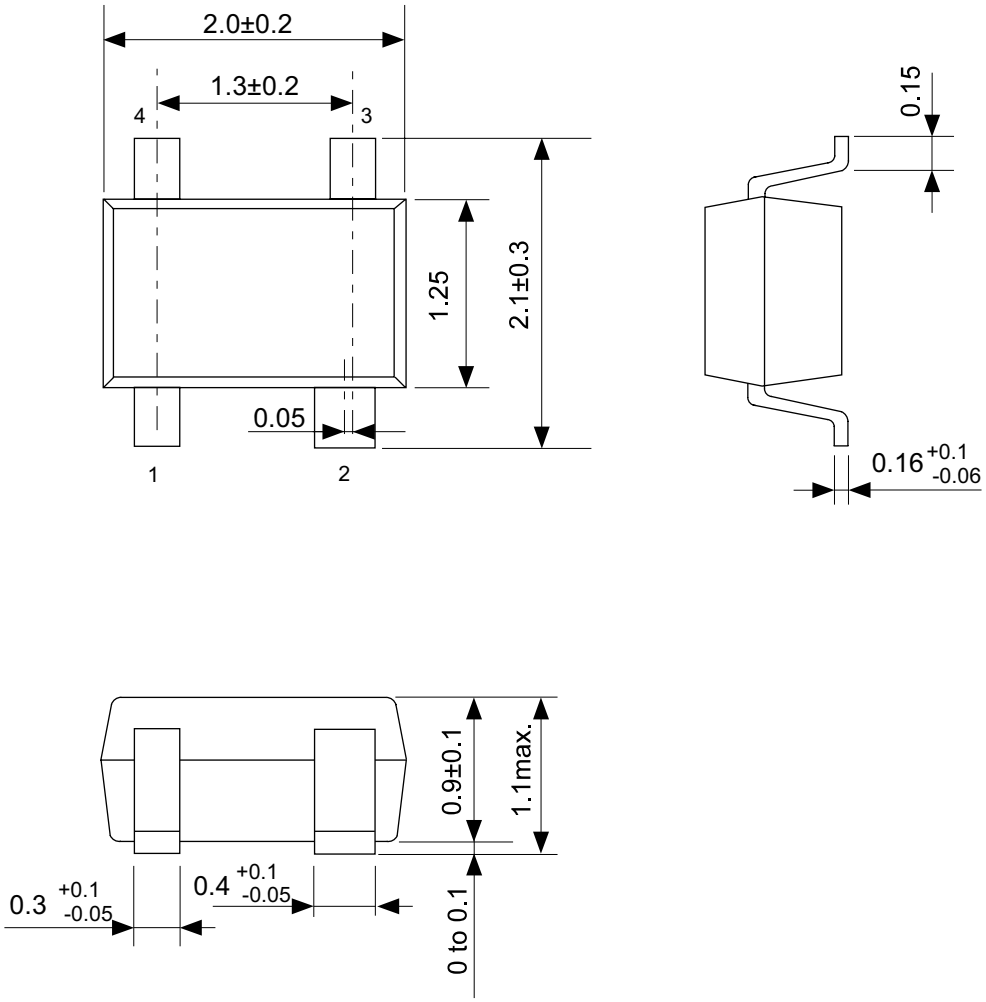
Caution 1. Do not do silkscreen printing and solder printing under the mold resin of the package.
2. The thickness of the solder resist on the wire pattern under the package should be 0.03 mm or less from the land pattern surface.
3. Match the mask aperture size and aperture position with the land pattern.
4. Refer to "SNT Package User's Guide" for details.

※**1.** 请注意焊盘模式的宽度 (0.25 mm min. / 0.30 mm typ.)。
※**2.** 请请勿向封装中间扩展焊盘模式 (1.10 mm ~ 1.20 mm)。

注意 **1.** 请勿在树脂型封装的下面印刷丝网、焊锡。
2. 在封装下、布线上的阻焊膜厚度 **(**从焊盘模式表面起**)** 请控制在**0.03 mm**以下。
3. 掩膜的开口尺寸和开口位置请与焊盘模式对齐。
4. 详细内容请参阅 **"SNT**封装的应用指南**"**。

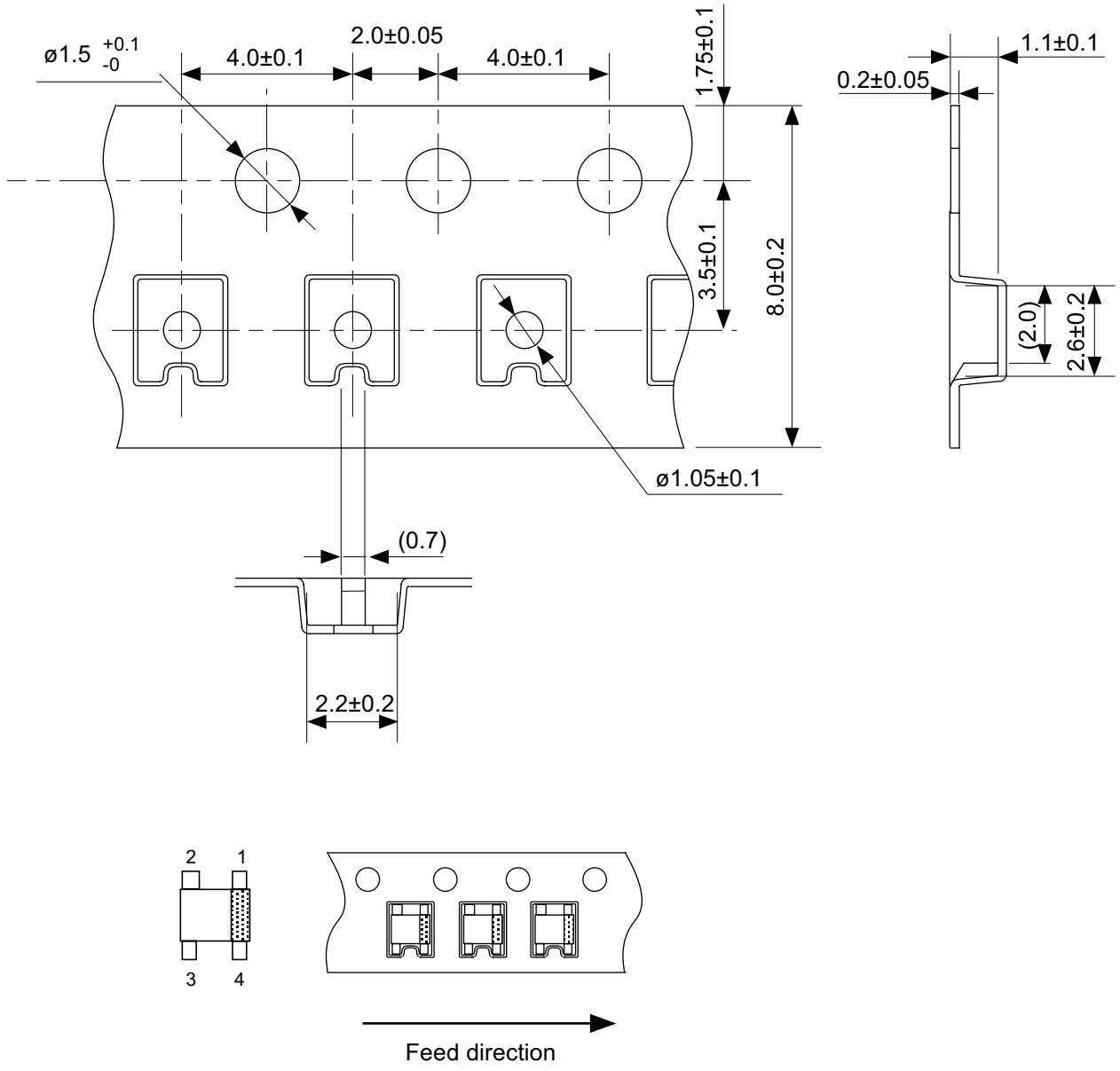
No. PF004-A-L-SD-4.0

TITLE	SNT-4A-A-Land Recommendation
No.	PF004-A-L-SD-4.0
SCALE	
UNIT	mm
Seiko Instruments Inc.	



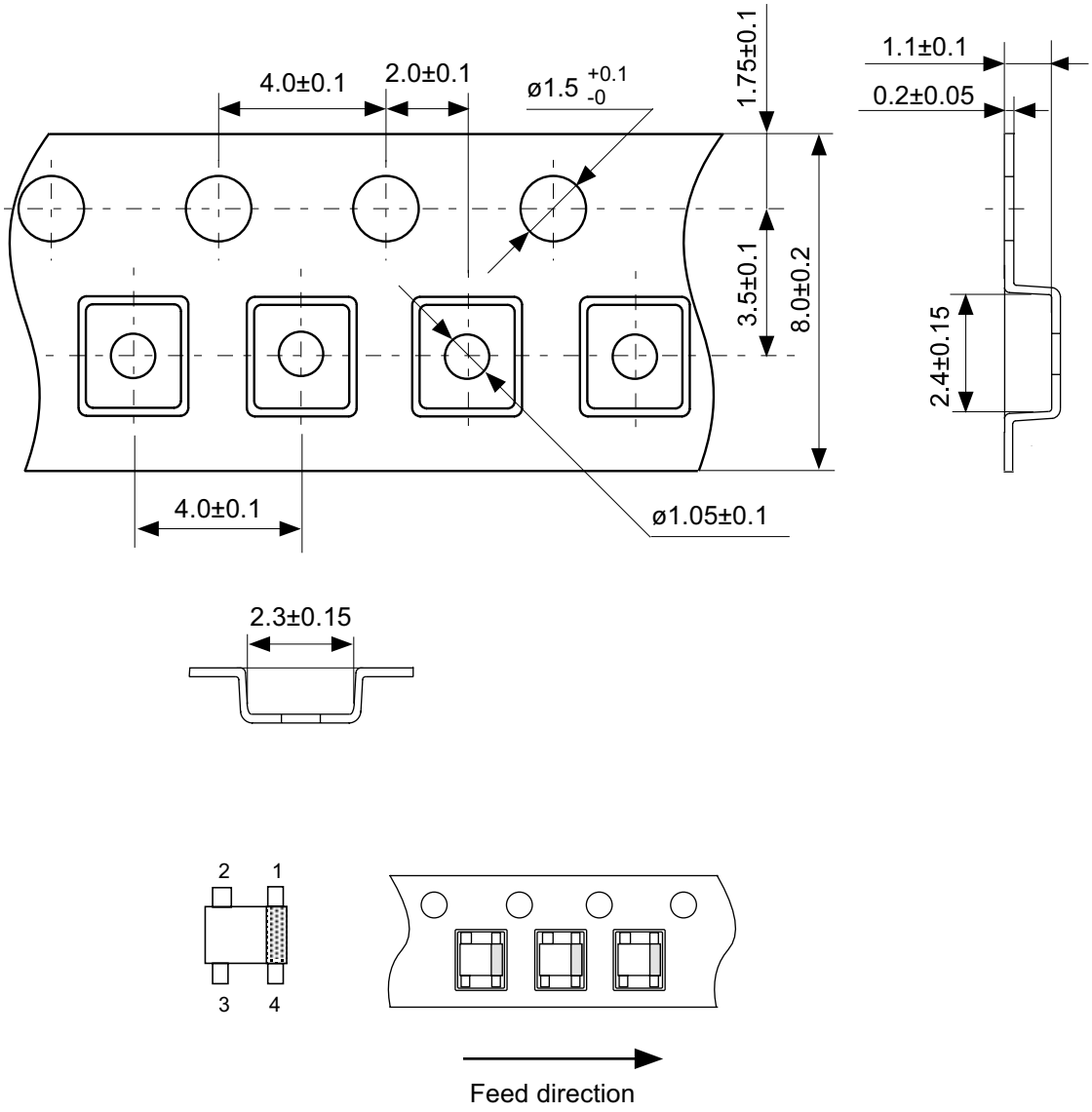
No. NP004-A-P-SD-1.1

TITLE	SC82AB-A-PKG Dimensions
No.	NP004-A-P-SD-1.1
SCALE	
UNIT	mm
Seiko Instruments Inc.	



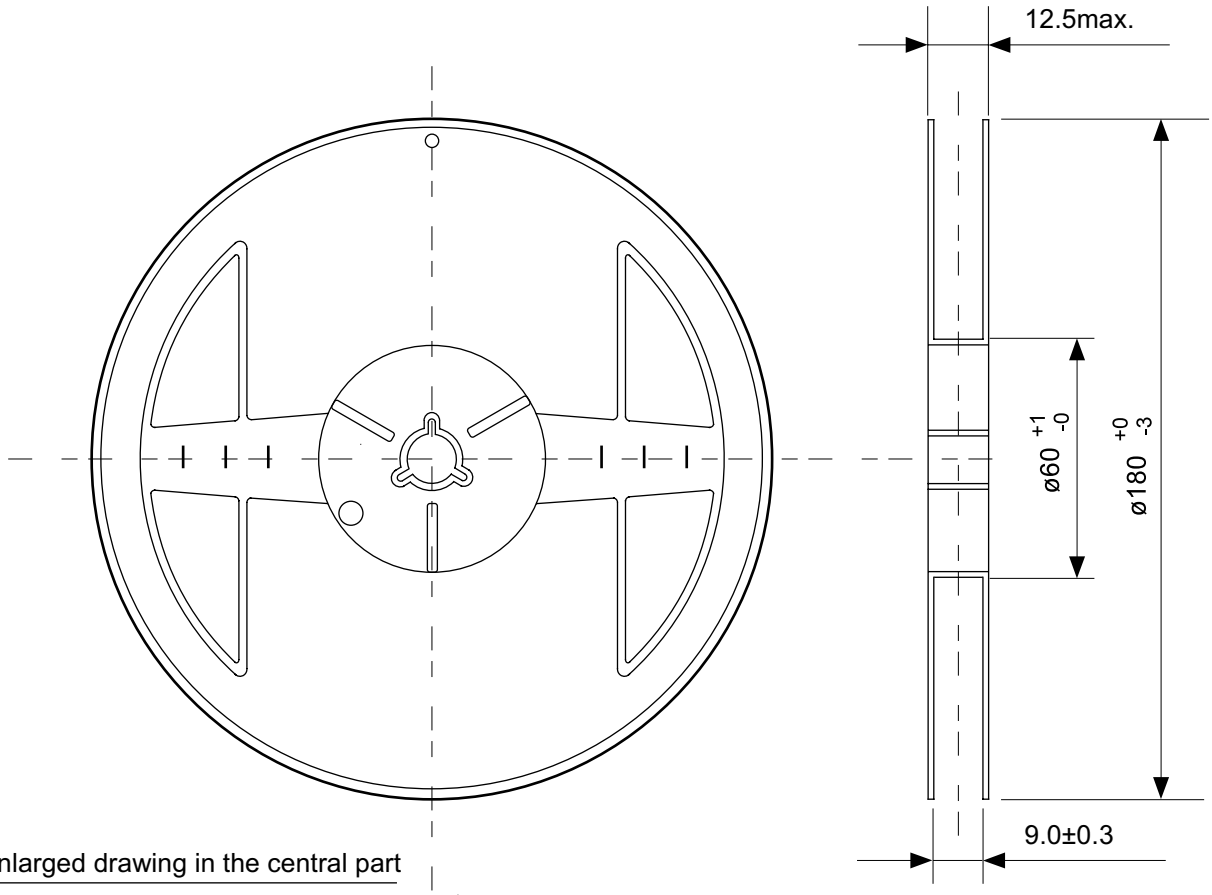
No. NP004-A-C-SD-3.0

TITLE	SC82AB-A-Carrier Tape
No.	NP004-A-C-SD-3.0
SCALE	
UNIT	mm
Seiko Instruments Inc.	

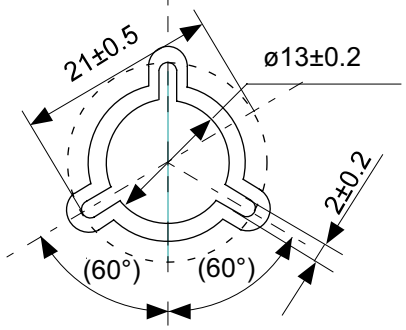


No. NP004-A-C-S1-2.0

TITLE	SC82AB-A-Carrier Tape
No.	NP004-A-C-S1-2.0
SCALE	
UNIT	mm
Seiko Instruments Inc.	

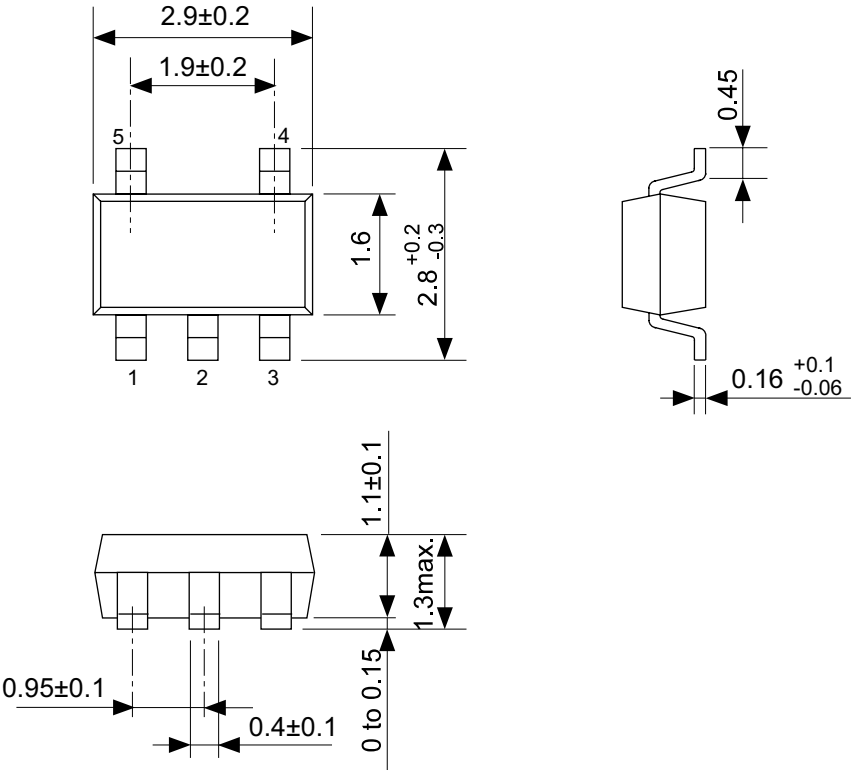


Enlarged drawing in the central part



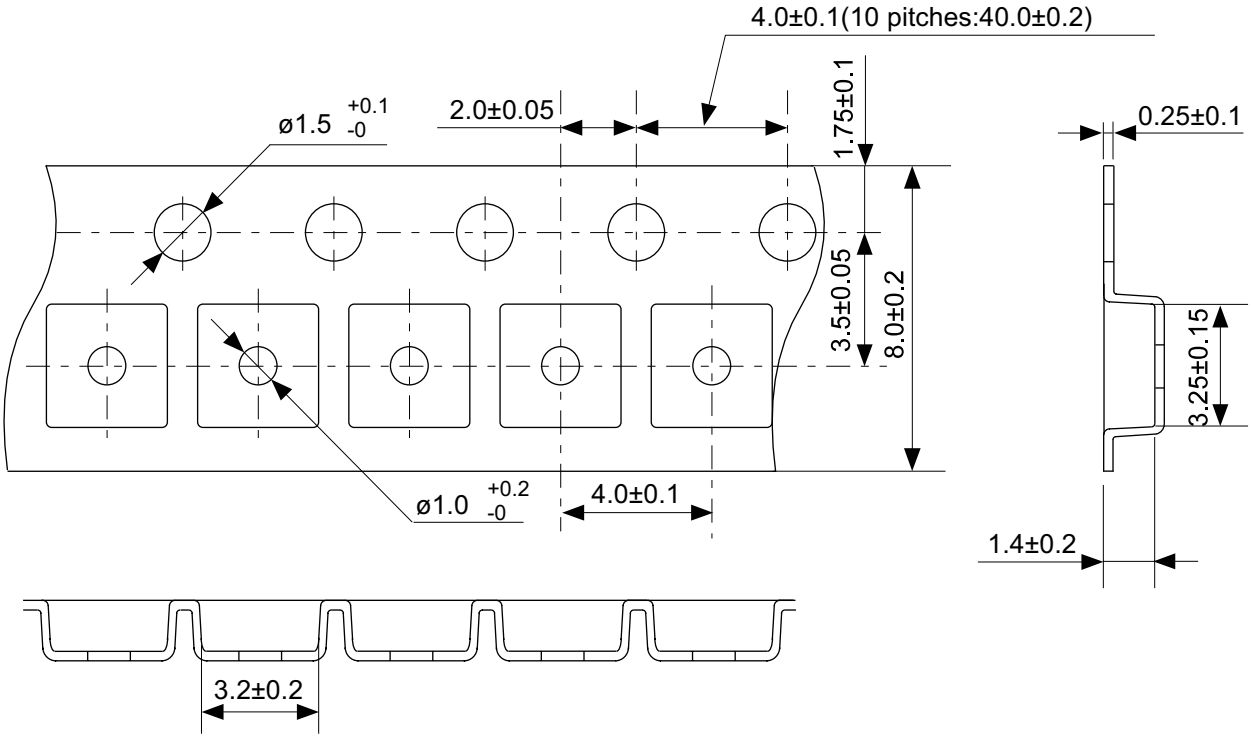
No. NP004-A-R-SD-1.1

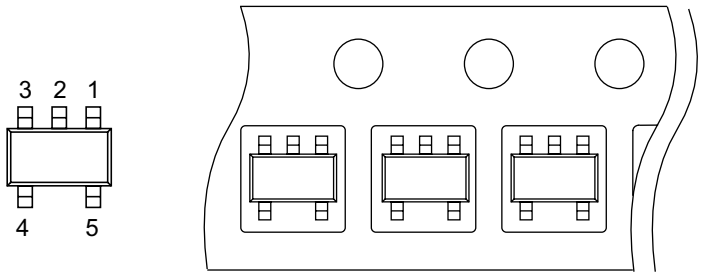
TITLE	SC82AB-A-Reel		
No.	NP004-A-R-SD-1.1		
SCALE		QTY.	3,000
UNIT	mm		
Seiko Instruments Inc.			



No. MP005-A-P-SD-1.2

TITLE	SOT235-A-PKG Dimensions
No.	MP005-A-P-SD-1.2
SCALE	
UNIT	mm
Seiko Instruments Inc.	

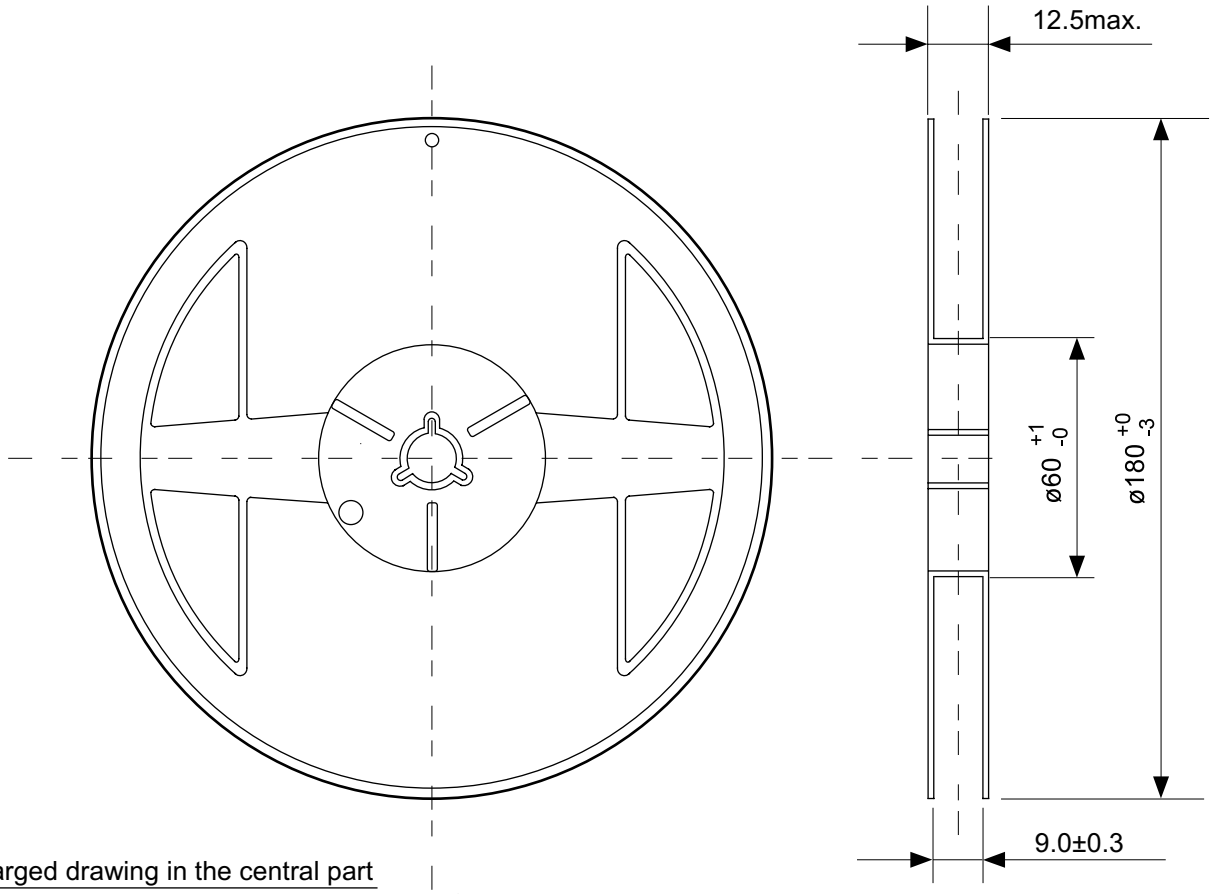




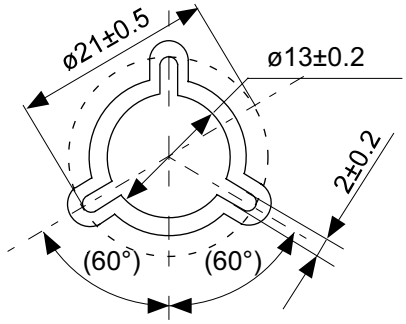
Feed direction

No. MP005-A-C-SD-2.1

TITLE	SOT235-A-Carrier Tape
No.	MP005-A-C-SD-2.1
SCALE	
UNIT	mm
Seiko Instruments Inc.	

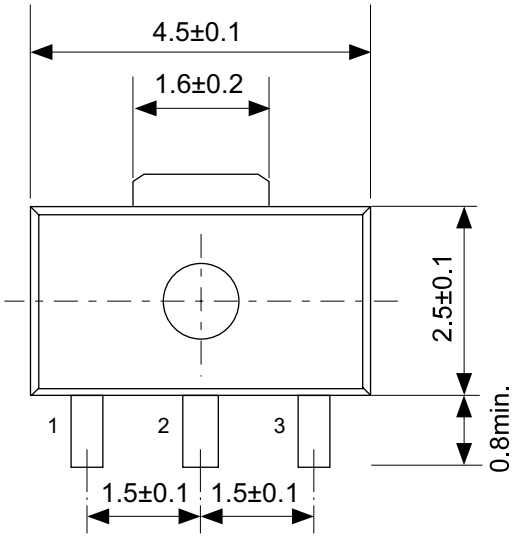


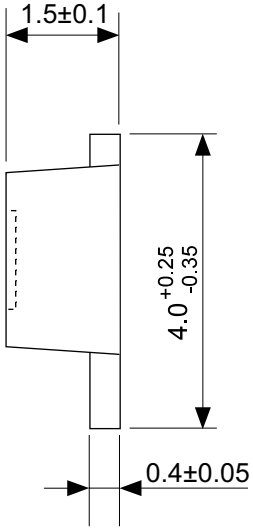
Enlarged drawing in the central part

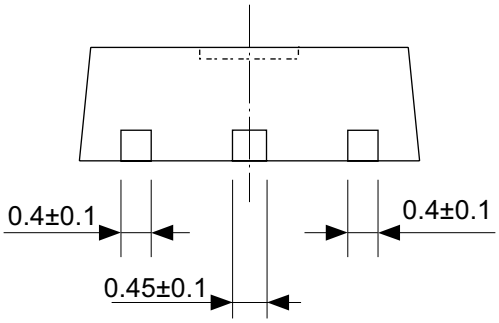


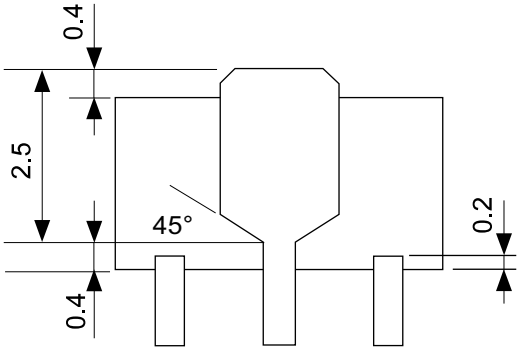
No. MP005-A-R-SD-1.1

TITLE	SOT235-A-Reel		
No.	MP005-A-R-SD-1.1		
SCALE		QTY.	3,000
UNIT	mm		
Seiko Instruments Inc.			



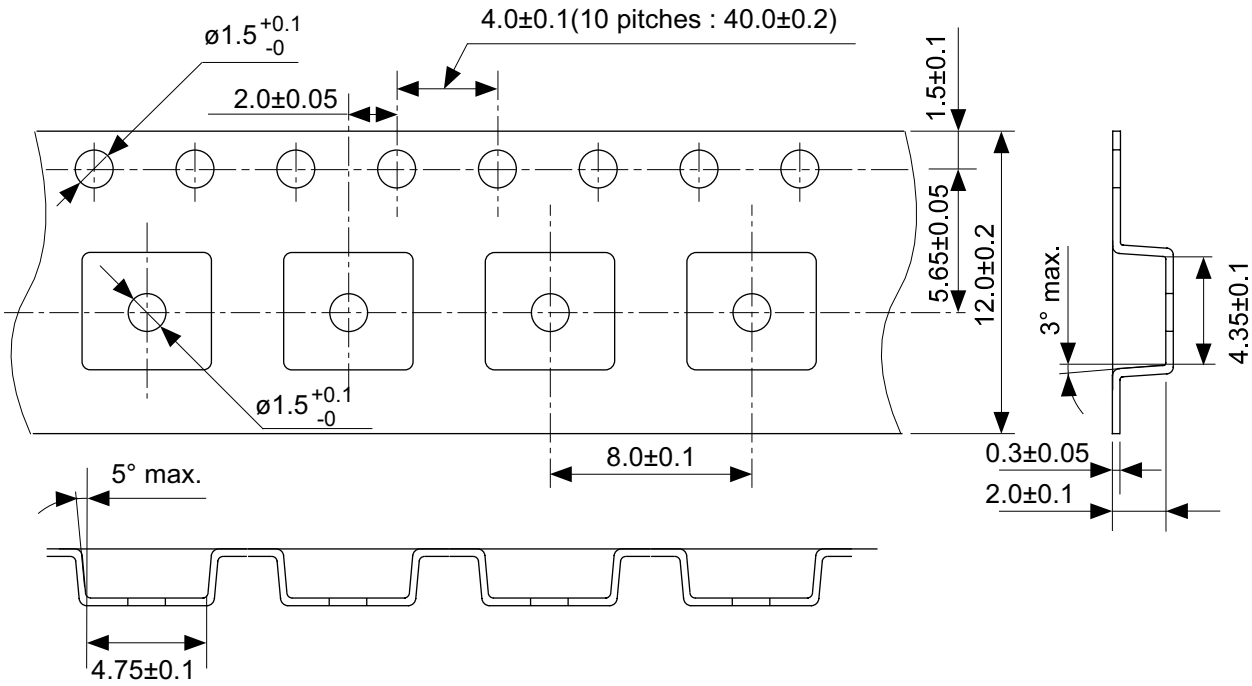


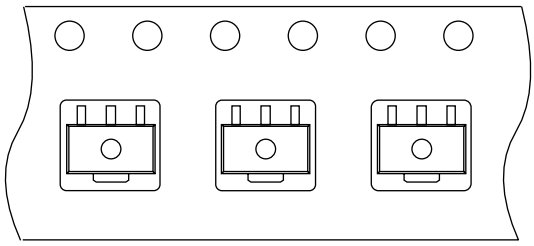




No. UP003-A-P-SD-1.1

TITLE	SOT893-A-PKG Dimensions
No.	UP003-A-P-SD-1.1
SCALE	
UNIT	mm
Seiko Instruments Inc.	

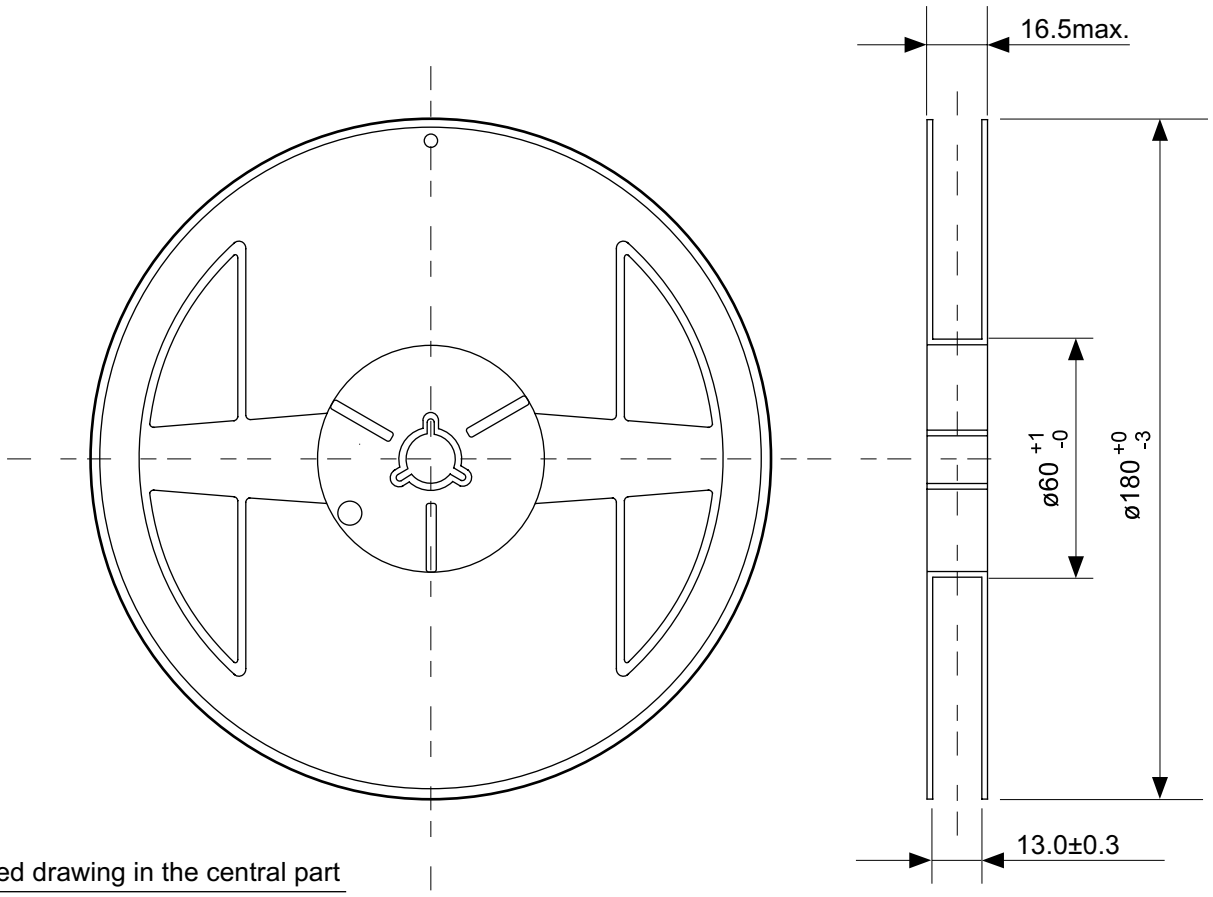




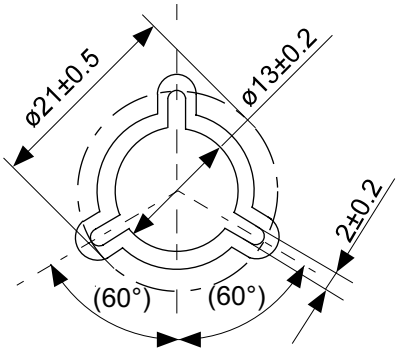
Feed direction

No. UP003-A-C-SD-1.1

TITLE	SOT893-A-Carrier Tape
No.	UP003-A-C-SD-1.1
SCALE	
UNIT	mm
Seiko Instruments Inc.	

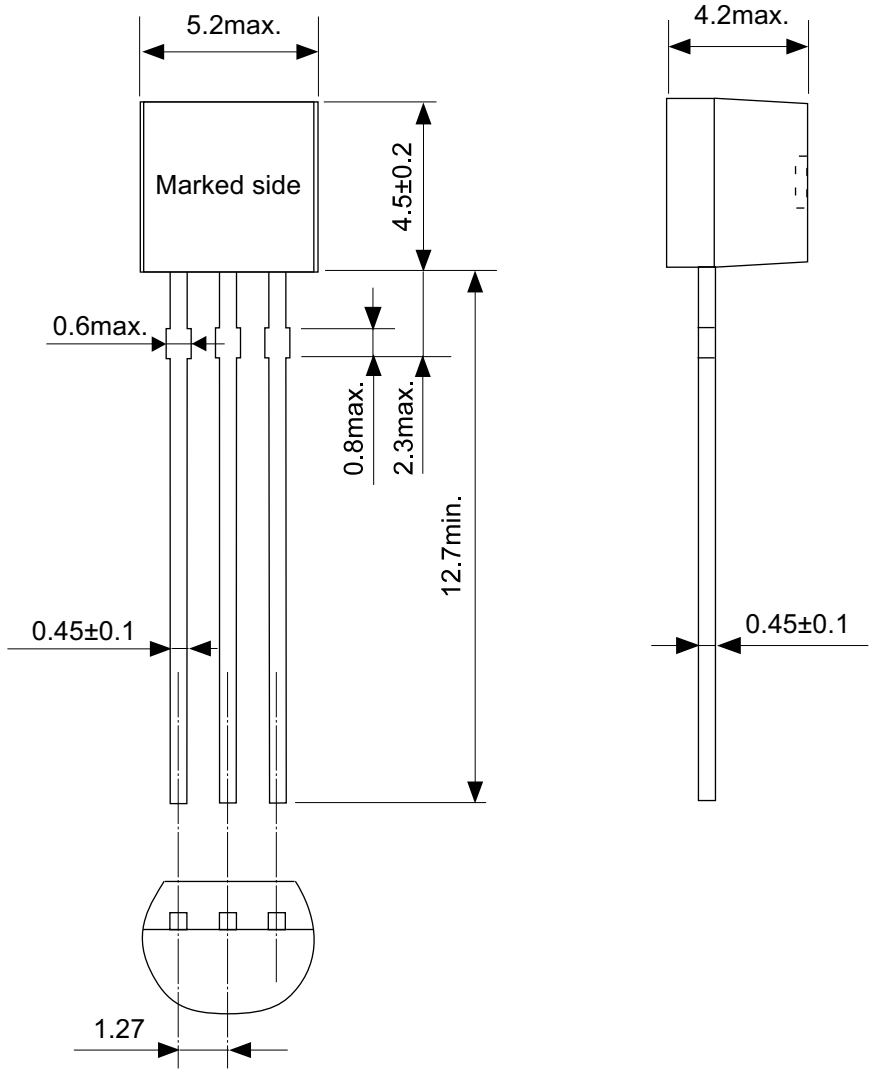


Enlarged drawing in the central part



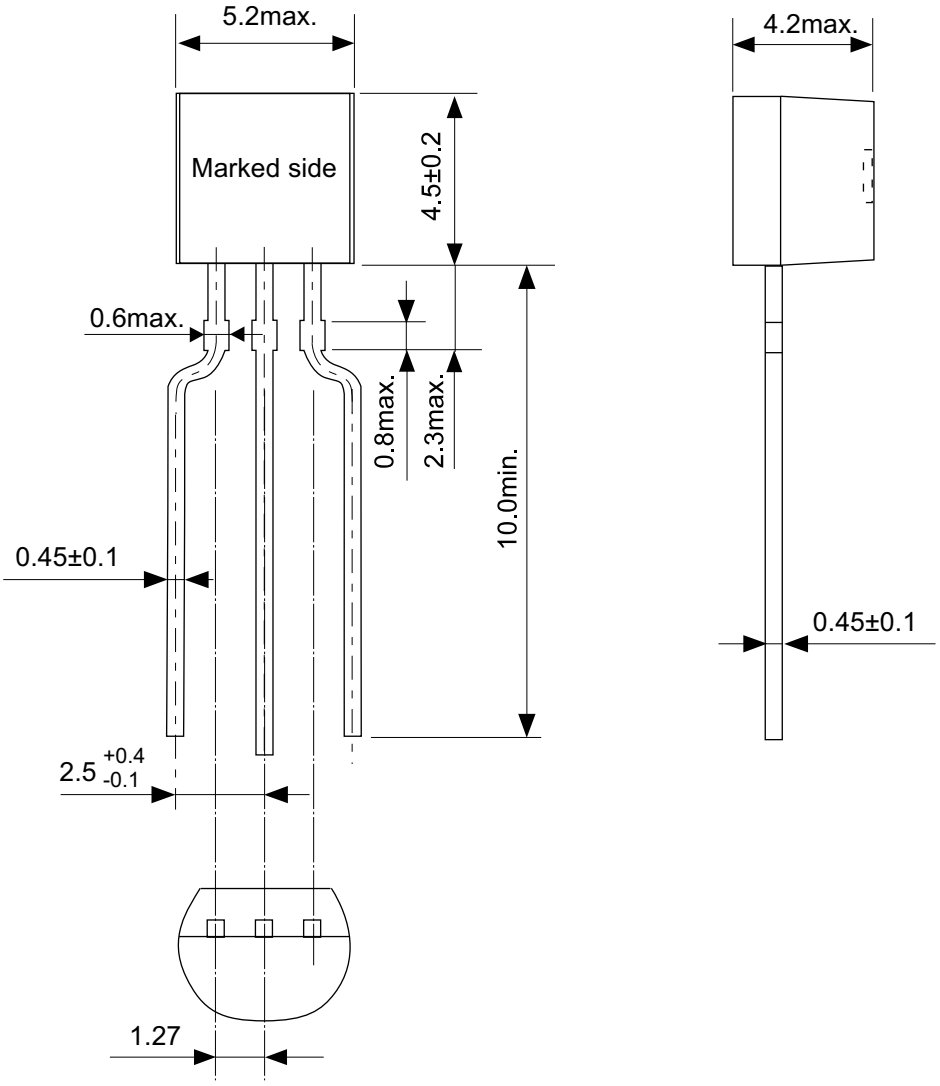
No. UP003-A-R-SD-1.1

TITLE	SOT893-A-Reel		
No.	UP003-A-R-SD-1.1		
SCALE		QTY.	1,000
UNIT	mm		
Seiko Instruments Inc.			



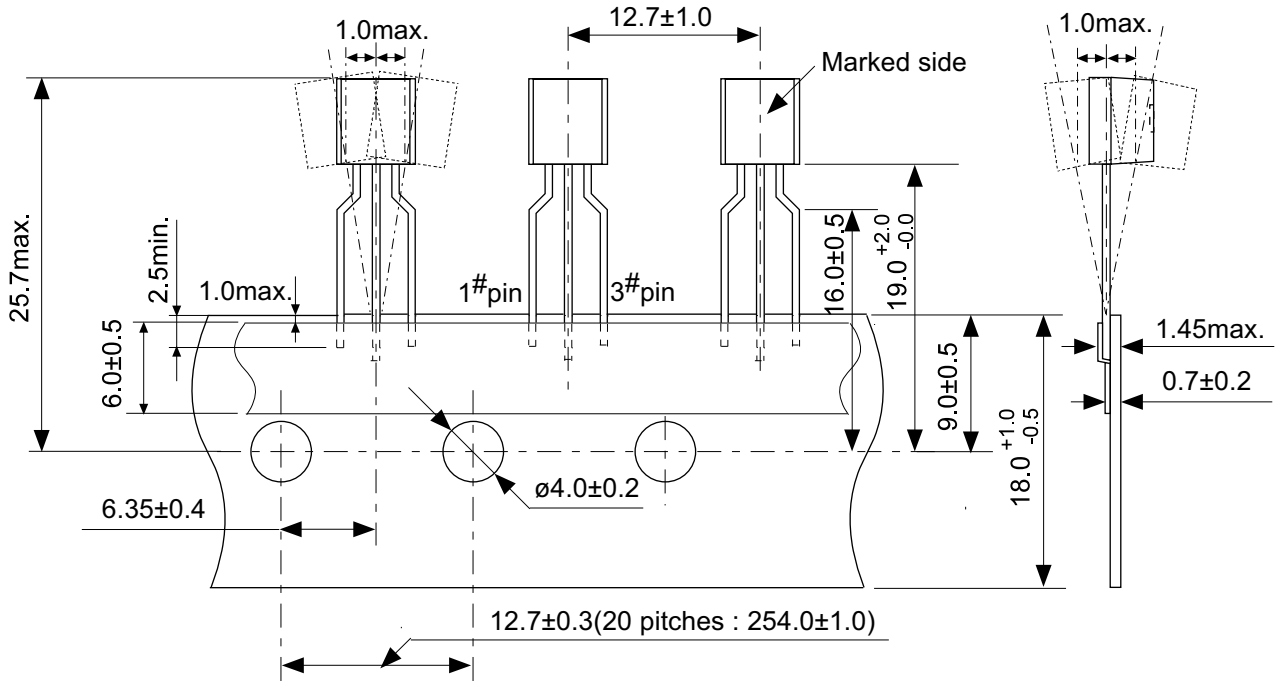
No. YS003-D-P-SD-2.0

TITLE	TO92-D-PKG Dimensions
No.	YS003-D-P-SD-2.0
SCALE	
UNIT	mm
Seiko Instruments Inc.	

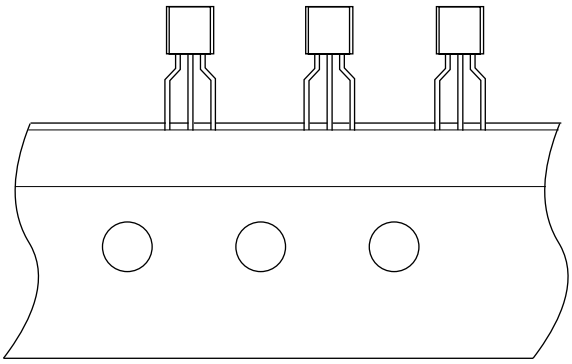


No. YZ003-E-P-SD-2.0

TITLE	TO92-E-PKG Dimensions
No.	YZ003-E-P-SD-2.0
SCALE	
UNIT	mm
Seiko Instruments Inc.	



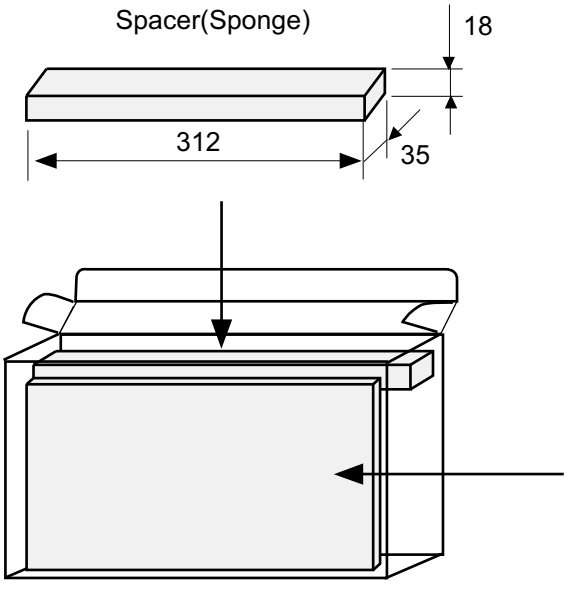
Z type

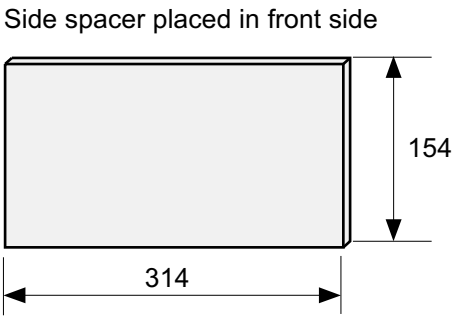


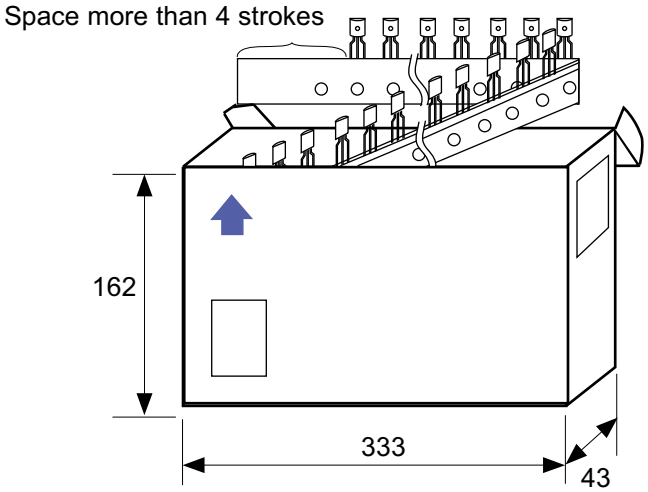
Feed direction

No. YZ003-E-C-SD-1.1

TITLE	TO92-E-Radial Tape
No.	YZ003-E-C-SD-1.1
SCALE	
UNIT	mm
Seiko Instruments Inc.	







No. YZ003-E-Z-SD-2.0

TITLE	TO92-E-Ammo Packing		
No.	YZ003-E-Z-SD-2.0		
SCALE		QTY.	2,000
UNIT	mm		
Seiko Instruments Inc.			

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